

Model spin-orbit coupling Hamiltonians for graphene systems

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We present a detailed theoretical study of effective spin-orbit coupling (SOC) Hamiltonians for graphene-based systems, covering global effects such as proximity to substrates and local SOC effects resulting, for example, from dilute adsorbate functionalization. Our approach combines group theory and tight-binding descriptions. We consider structures with global point group symmetries D_{6h} , D_{3d} , D_{3h} , C_{6v} , and C_{3v} that represent, for example, pristine graphene, graphene miniripple, planar boron nitride, graphene on a substrate, and free standing graphene, respectively. The presence of certain spin-orbit coupling parameters is correlated with the absence of the specific point group symmetries. Especially in the case of C_{6v} —graphene on a substrate, or transverse electric field—we point out the presence of a third SOC parameter, besides the conventional intrinsic and Rashba contributions, thus far neglected in literature. For all global structures we provide effective SOC Hamiltonians both in the local atomic and Bloch forms. Dilute adsorbate coverage results in the local point group symmetries C_{6v} , C_{3v} , and C_{2v} , which represent the stable adsorption at hollow, top and bridge positions, respectively. For each configuration we provide effective SOC Hamiltonians in the atomic orbital basis that respect local symmetries. In addition to giving specific analytic expressions for model SOC Hamiltonians, we also present general (no-go) arguments about the absence of certain SOC terms.

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I. INTRODUCTION

The ability to synthesize, manipulate, and functionalize 2D materials is an ultimate milestone in technological development and current fundamental research, including spintronics [1,2]. One of the major challenges is controlling, engineering, and harvesting spin degrees of freedom for faster data processing, storage, etc. Graphene seems to be a promising material [3] for such applications due to its high bipolar mobility [4], chemical and mechanical [5] stability, “relativistic” band structure [6] with chiral electrons that are highly insensitive to backscattering [7,8], and, importantly for spintronics, weak intrinsic spin-orbit coupling (SOC) [9]. The latter was theoretically estimated [10–14] to yield long spin lifetimes—orders of microseconds—enough for harvesting electron spins as “carriers of information.” However, experiments carried out on graphene devices of the first generation gave spin lifetimes three orders of magnitude smaller [15–21]. This vast discrepancy can be reliably explained assuming a small amount (orders of ppm) of resonant magnetic scatters [22–24] like for example hydrogen atoms [25,26] or vacancies [26,27]. Related theoretical studies [28–30] confirmed that magnetic moments, indeed, strongly affect spin dynamics and can cause the ultra-fast spin relaxation. A recent experiment of the Valenzuela group [31], analyzing graphene’s spin-lifetime anisotropy, supports that view and convincingly rules out SOC as a determining factor of the fast spin relaxation.

On the other hand, enhancing SOC in graphene is desirable as well. Indeed, graphene with strong intrinsic SOC is predicted to host the quantum spin Hall phase [32]. Therefore, one of the current technological and theoretical challenges is to tailor the strength of SOC of graphene in a controllable manner. In fact, SOC can be significantly enhanced either by chemical functionalization—coating of graphene with light [33–39] or heavy [40–43] adatoms—accompanied by band gap opening,

curvature as in the case of carbon nanotubes [44,45], or by a variety of proximity effects resulting from substrates or due to scaffolding of different 2D materials [46]. Tangible examples are CVD graphene grown on Cu and Ni substrates [47–49], or graphene placed on top of transition metal dichalcogenides [50–53].

To further examine SOC effects in functionalized graphene and also design device properties, one needs an effective model that allows reliable simulations of the spin and charge transport characteristics [28,54–68]. In this paper, we present a detailed symmetry analysis focusing on effective SOC Hamiltonians in a way that is complementary to Refs. [40,58,69]. Our findings remain valid for any hexagonal (graphenelike) structure possessing π orbitals and are easily transferable to other systems. The primary aim of this manuscript is to lift the curtain and show practically how to derive the corresponding SOC Hamiltonians from the given pools of global or local symmetries.

We discuss two cases: global SOC Hamiltonians that represent proximity induced phenomena or periodically functionalized structures, and local SOC Hamiltonians that govern spin dynamics in the vicinity of adsorbates. Starting with pristine graphene, we step-by-step reduce the number of global symmetries approaching structures such as graphene miniripple, staggered graphene, planar boron nitride, silicene, graphene on a substrate, graphone, etc. For each representative case, which is classified by the associated subgroup of the full hexagonal group, we derive an effective SOC Hamiltonian in real and reciprocal spaces, respectively. Our analysis therefore covers also quasimomenta that are not necessarily constrained to the vicinity of Dirac points.

In the case of local impurities, we focus on the reduction of local symmetries up to a certain spatial extent from the adsorbate. The three representative adsorption positions are hollow, top, and bridge and we provide here the local SOC Hamiltonians in real space. Group arguments allow us to link the presence or absence of certain symmetries to various spin-orbit couplings that emerge in the effective SOC Hamiltonian. For example, in the global case corresponding to point group

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C_{6v} —graphene in a transverse electric field or deposited on a substrate—we highlight the presence of a SOC term that have not yet been considered. It appears along with the conventional intrinsic and Rashba couplings and is related to the absence of the principal mirror plane in the structure.

The paper is organized as follows. After recapitulating the basic group theory related with the full hexagonal system and its application to SOC matrix elements in Sec. II, we discuss separately translational invariant systems, Sec. III, and systems lacking that invariance (local adsorbates), Sec. IV. In sections of III, we cover in detail SOC in pristine graphene, point group D_{6h} , and effective SOC Hamiltonians in systems that are characterized by one of its subgroups: D_{3d} , D_{3h} , C_{6v} , and C_{3v} . Section IV is devoted to local SOC Hamiltonians for the three stable adsorption positions—hollow, top, and bridge, respectively. Summary and final remarks are provided in Sec. V.

II. GROUP THEORY AND SOC: PRELIMINARIES

A convenient approach how the group theory enters effective model building is a decomposition of the Hamiltonian matrix elements associated with the problem into irreducible representations (irreps). Those are well known and standardly tabulated for all crystallographic point groups [70,71]. Considering spin and spin-orbit interaction the irrep analysis around the high-symmetry points in the Brillouin zone becomes more involved. This is because the associated double (also called spinor) group representations should be appropriately taken into account; the case of graphite is exhaustively discussed in the thesis of Slonczewski [72]. For a general overview and connection with the theory of group invariants, see the book of Bir and Pikus [73], or Winkler [74].

Another possibility how to derive an effective SOC Hamiltonian is to employ the multi-orbital tight-binding approach [75–78]. The group symmetry analysis on the orbital level is straightforward and well described by the Koster-Slater two-center approximation [79] and, consequently, SOC enters as the intra-atomic LS interaction $\xi_\ell \hat{L} \cdot \hat{S}$. The resulting multi-orbital tight-binding Hamiltonian is then downfolded by means of the Löwdin projection [80] to the states of interest—mostly the low-energy states with respect to the Fermi level.

As an alternative to the invariant expansion and the multi-orbital tight-binding method with the Löwdin projection, we present here an effective tight-binding approach that employs symmetries of local atomic orbitals. We focus particularly on hexagonal lattice structures assuming the low-energy physics near the Fermi level can be approximately well described by π orbitals, i.e., carbon $2p_z$ orbitals, or atomic orbitals $n, \ell \neq 0, m_\ell = 0$. For simplicity, we consider that each nodal atomic site m contains one effective π -orbital state, $|X_m\rangle \equiv c_m^\dagger |0\rangle$. When it is necessary to specify the sublattice X , we explicitly write $|A_m\rangle$ and $|B_m\rangle$ for the two atomic sites in a hexagonal lattice. Including also electron spin, $\sigma = \{\uparrow, \downarrow\} \equiv \{+1, -1\}$, the effective one-particle Hilbert space is spanned by states $|X_m\sigma\rangle \equiv c_{m,\sigma}^\dagger |0\rangle$.

The structural point group of an ideal hexagonal lattice is the symmetry group D_{6h} —in international crystallographic notation group $6/mmm$. It contains 24 group elements which can be expressed in terms of four group generators: identity

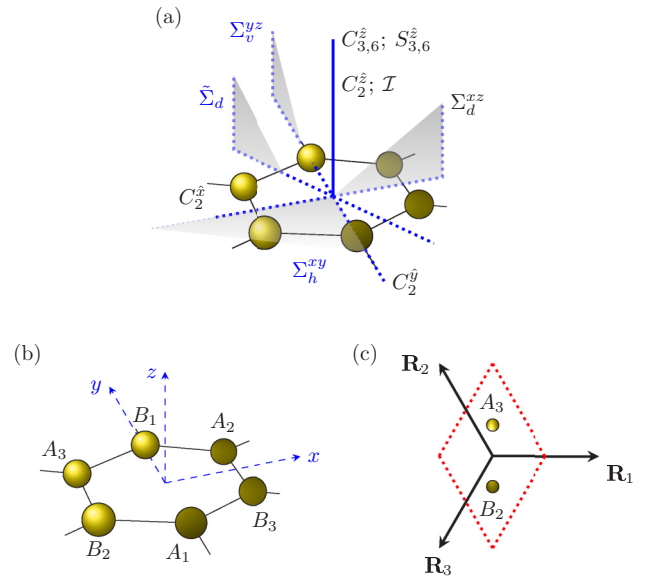


FIG. 1. Panel (a) shows selected symmetry operations of point group D_{6h} . Combining the point group generators (blue symbols)—horizontal Σ_h^{xy} , vertical Σ_v^{yz} , and dihedral $\tilde{\Sigma}_d$ reflections, one can build all the remaining group elements (black symbols). Lower panels depict (b) sites' labeling convention and axes orientation, and (c) graphene unit cell together with the Bravais lattice vectors \mathbf{R}_α ($\alpha = 1, 2, 3$).

E and reflections $\Sigma_h \equiv \Sigma_h^{xy}$, $\Sigma_v \equiv \Sigma_v^{yz}$, $\tilde{\Sigma}_d$, for visualization see Fig. 1. Subscripts h , v , and d stand for the horizontal (xy plane), vertical (yz plane), and dihedral (rotated xz plane) reflections, respectively. When it is convenient to emphasize the reflection planes explicitly, we employ the superscripts xz , yz , and xy . Similarly, to specify the axis determining a spatial rotation we use hat superscripts, such as \hat{x} , \hat{y} , and \hat{z} . The remaining elements of D_{6h} are sixfold and threefold rotations, $C_6^{\hat{z}} = \tilde{\Sigma}_d \circ \Sigma_v$ and $C_3^{\hat{z}} = C_6^{\hat{z}} \circ C_6^{\hat{z}}$, the xz -dihedral reflection $\Sigma_d \equiv \Sigma_d^{xz} = C_3^{\hat{z}} \circ \tilde{\Sigma}_d$, the space inversion $\mathcal{I} = \Sigma_h \circ \Sigma_d \circ \Sigma_v$, the improper rotations $S_6^{\hat{z}} = \Sigma_h \circ C_6^{\hat{z}}$, $S_3^{\hat{z}} = \Sigma_h \circ C_3^{\hat{z}}$, and the twofold rotations $C_2^{\hat{x}} = \Sigma_h \circ \Sigma_d$, $C_2^{\hat{y}} = \Sigma_h \circ \Sigma_v$, and $C_2^{\hat{z}} = \Sigma_v \circ \Sigma_d$, see Fig. 1.

To construct an invariant SOC Hamiltonian, it is necessary to know how the one-particle basis states $|X_m\sigma\rangle$ transform under the active action of D_{6h} including the time reversal symmetry \mathcal{T} . While we are not dealing with the double group irreps it is enough to focus on the action of selected group elements: rotation $\mathcal{R}_\Phi^{\hat{z}}$ by an angle Φ , the horizontal, vertical, and dihedral reflections Σ_h , Σ_v , and Σ_d , respectively, the time reversal \mathcal{T} , and for completeness also the space inversion \mathcal{I} and the translation $T_{\vec{a}}$ by a lattice vector \vec{a} :

$$|X_m\sigma\rangle \xrightarrow{\mathcal{R}_\Phi} e^{-i\sigma\frac{\Phi}{2}} |X_{\mathcal{R}_\Phi(m)}\sigma\rangle, \quad (1a)$$

$$|X_m\sigma\rangle \xrightarrow{\Sigma_h^{xy}} i(-1)^{\frac{1+\sigma}{2}} |X_m\sigma\rangle, \quad (1b)$$

$$|X_m\sigma\rangle \xrightarrow{\Sigma_v^{yz}} i |X_{\Sigma_v^{yz}(m)}(-\sigma)\rangle, \quad (1c)$$

$$|X_m\sigma\rangle \xrightarrow{\Sigma_d^{xz}} (-1)^{\frac{1+\sigma}{2}} |X_{\Sigma_d^{xz}(m)}(-\sigma)\rangle, \quad (1d)$$

$$|X_m\sigma\rangle \xrightarrow{\mathcal{T}} (-1)^{\frac{1-\sigma}{2}} |X_m(-\sigma)\rangle, \quad (1e)$$

$$|X_m\sigma\rangle \xrightarrow{\mathcal{T}} -|X_{\mathcal{T}(m)}\sigma\rangle, \quad (1f)$$

$$|X_m\sigma\rangle \xrightarrow{\mathcal{T}_{\hat{a}}} |X_{m+\hat{a}}\sigma\rangle. \quad (1g)$$

The action of the remaining D_{6h} elements follow immediately from the relations to the group generators. The action of \mathcal{T} affects only the spin component of $|X_m\sigma\rangle = |X_m\rangle \otimes |\sigma\rangle$ since, by convention, our orbital π states $|X_m\rangle$ are real-valued wave functions.

An electron moving in an effective crystal field potential V is affected by SOC interaction that is represented by Hamiltonian,

$$\hat{H}_{\text{so}} = \frac{\hbar}{4m_e^2 c^2} (\nabla V \times \hat{\mathbf{p}}) \cdot \hat{\mathbf{s}}. \quad (2)$$

Here, m_e is the vacuum rest mass of the electron, c is the speed of light, $\hat{\mathbf{p}}$ stands for the momentum operator, and $\hat{\mathbf{s}} = (\hat{s}_x, \hat{s}_y, \hat{s}_z)$ represents the array of Pauli matrices acting on spin degrees of freedom. In reality, we do not know the crystal field and so \hat{H}_{so} exactly, but knowing the pool of symmetries preserving V , and hence \hat{H}_{so} , we can uniquely detect which matrix elements $\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma' \rangle$ are nonzero and thus important. If \mathcal{S} is a system's symmetry—precisely, its *unitary* representation—then $\mathcal{S}\hat{H}_{\text{so}} = \hat{H}_{\text{so}}\mathcal{S}$ and

$$\begin{aligned} \langle \mathcal{S}[X_m\sigma] | \hat{H}_{\text{so}} | \mathcal{S}[X_n\sigma'] \rangle &= \langle \mathcal{S}[X_m\sigma] | \mathcal{S}[\hat{H}_{\text{so}} X_n\sigma'] \rangle \\ &= \langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma' \rangle \end{aligned} \quad (3)$$

for any two one-particle states $|X_m\sigma\rangle$ and $|X_n\sigma'\rangle$. In an analogous way, we get for the *antiunitary* time reversal symmetry, $\mathcal{T}\hat{H}_{\text{so}} = \hat{H}_{\text{so}}\mathcal{T}$, and self-adjoint \hat{H}_{so}

$$\begin{aligned} \langle \mathcal{T}[X_m\sigma] | \hat{H}_{\text{so}} | \mathcal{T}[X_n\sigma'] \rangle &= \langle \mathcal{T}[X_m\sigma] | \mathcal{T}[\hat{H}_{\text{so}} X_n\sigma'] \rangle \\ &= \overline{\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma' \rangle} \\ &= \langle X_n\sigma' | \hat{H}_{\text{so}} | X_m\sigma \rangle. \end{aligned} \quad (4)$$

This gives us a practical relation connecting SOC matrix elements with opposite spin projections:

$$\begin{aligned} \langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma' \rangle &\stackrel{(1e)}{=} \langle (-1)^{-\frac{1-\sigma}{2}} \mathcal{T}[X_m(-\sigma)] | \hat{H}_{\text{so}} | (-1)^{-\frac{1-\sigma'}{2}} \mathcal{T}[X_n(-\sigma')] \rangle \\ &= -(-1)^{\frac{\sigma+\sigma'}{2}} \langle \mathcal{T}[X_m(-\sigma)] | \hat{H}_{\text{so}} | \mathcal{T}[X_n(-\sigma')] \rangle \\ &\stackrel{(4)}{=} -(-1)^{\frac{\sigma+\sigma'}{2}} \langle X_n(-\sigma') | \hat{H}_{\text{so}} | X_m(-\sigma) \rangle. \end{aligned} \quad (5)$$

In practice, we focus only on the on-site, nearest neighbors, and the next-nearest-neighbor SOC mediated hoppings $\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma' \rangle$. This is sufficient because the orbital overlaps modulated by ∇V —dominant near the atomic cores—decay rather fast with increasing distance. Therefore we focus on SOC hoppings $\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma' \rangle$ inside one particular elementary cell of the hexagonal lattice, see Fig. 1. All other spin-resolved hoppings can be expressed by applying translations, rotations, reflections, or time reversal, see Eqs. (1).

In what follows we show how time reversal symmetry and self-adjointness of \hat{H}_{so} restrict $\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma' \rangle$. Particularly, we argue that the spin-conserving hoppings $\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma \rangle$ are purely imaginary, and the on-site SOC resolved hoppings

$\langle X_m\sigma | \hat{H}_{\text{so}} | X_m\sigma \rangle$ and $\langle X_m\sigma | \hat{H}_{\text{so}} | X_m(-\sigma) \rangle$ vanish. First, note that the SOC Hamiltonian \hat{H}_{so} , Eq. (2), can be recast into the form

$$\hat{H}_{\text{so}} = \hat{\mathcal{L}}_+ \hat{s}_- + \hat{\mathcal{L}}_- \hat{s}_+ + \hat{\mathcal{L}}_z \hat{s}_z, \quad (6)$$

where $\hat{s}_{\pm} = \frac{1}{2}(\hat{s}_x \pm i\hat{s}_y)$ are spin raising and lowering operators (without $\frac{\hbar}{2}$) and $\hat{\mathcal{L}}_i$'s act solely on the orbital part of the wave function. It follows from the hermiticity of \hat{H}_{so} that $\hat{\mathcal{L}}_-^\dagger = \hat{\mathcal{L}}_+$ and $\hat{\mathcal{L}}_z$ is self-adjoint. Also \mathcal{L} 's transform under the space and time reversal symmetries equally as the standard angular momentum operators. However, for a general crystal field potential V they do not obey the usual SU(2)-commutation relations. Directly from Eq. (6) we have

$$\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma \rangle = -\langle X_m(-\sigma) | \hat{H}_{\text{so}} | X_n(-\sigma) \rangle. \quad (7)$$

On the other side, the time reversal symmetry, Eq. (5), implies

$$\begin{aligned} \langle X_m(-\sigma) | \hat{H}_{\text{so}} | X_n(-\sigma) \rangle &\stackrel{(5)}{=} \langle X_n\sigma | \hat{H}_{\text{so}} | X_m\sigma \rangle \\ &= \overline{\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma \rangle}. \end{aligned} \quad (8)$$

So comparing this and the above expression, we see that

$$\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma \rangle \quad (9)$$

is a purely imaginary SOC matrix element for any two atomic sites mediating a spin-conserving hopping. In the special case $m = n$, the above Eqs. (5) and (7) give

$$\begin{aligned} \langle X_m\sigma | \hat{H}_{\text{so}} | X_m\sigma \rangle &\stackrel{(5)}{=} \langle X_m(-\sigma) | \hat{H}_{\text{so}} | X_m(-\sigma) \rangle \\ &\stackrel{(7)}{=} -\langle X_m\sigma | \hat{H}_{\text{so}} | X_m\sigma \rangle, \end{aligned} \quad (10)$$

so that we have shown that *the on-site spin-conserving term $\langle X_m\sigma | \hat{H}_{\text{so}} | X_m\sigma \rangle$ equals zero for any site m* . In a similar way we get for its spin-flipping counterpart:

$$\langle X_m\sigma | \hat{H}_{\text{so}} | X_m(-\sigma) \rangle \stackrel{(5)}{=} -\langle X_m\sigma | \hat{H}_{\text{so}} | X_m(-\sigma) \rangle, \quad (11)$$

so *the on-site spin-flipping matrix element $\langle X_m\sigma | \hat{H}_{\text{so}} | X_m(-\sigma) \rangle$ is zero for any lattice site m* . Therefore what matters are the nearest- and next-nearest-neighbor SOC mediated matrix elements, which we will examine in the forthcoming sections.

III. TRANSLATIONAL INVARIANT SYSTEMS

A. Pristine graphene SOC Hamiltonian

The spin-orbit coupling Hamiltonian based on π states that is translational invariant and possesses the full point group symmetry D_{6h} of the pristine graphene allows only one, the so called intrinsic, SOC hopping λ_1 . This was first discussed by McClure and Yafet [81] when analyzing the g factor in a “graphite single crystal.” Later Kane and Mele [32] revisited this point when predicting the quantum spin Hall effect in graphene. The magnitude of λ_1 was found in the work of Gmitra *et al.* [9], who showed that λ_1 is too weak—about 12 μeV —to induce an experimentally detectable transition into the quantum spin Hall phase. Furthermore, Gmitra *et al.* [9] found that λ_1 is due to the coupling of p_z and d orbitals. This was supported by multiorbital tight-binding calculations; Kunschuh *et al.* [75] showed that the intrinsic SOC hopping

λ_I is significantly affected by the admixture of $3d_{xz} \pm i3d_{yz}$ orbitals, the fact anticipated already by Slonczewski [72].

The effective tight-binding Hamiltonian mediating the SOC interaction among π states in graphene—or any planar hexagonal system with one π -orbital per site—reads

$$\mathcal{H}_{D_{6h}} = \frac{i\lambda_I}{3\sqrt{3}} \sum_{\sigma} \sum_{\langle(m,n)\rangle} v_{m,n} [\hat{s}_z]_{\sigma\sigma} |X_m\sigma\rangle \langle X_n\sigma|. \quad (12)$$

The Hamiltonian $\mathcal{H}_{D_{6h}}$ couples next-nearest neighbors (summation over $\langle(m,n)\rangle$) and allows only spin-conserving hoppings. Therefore, in accordance with Eq. (9), the underlying coupling constant is purely imaginary. Using the configuration shown at Fig. 1, the coupling $i\lambda_I$ can be defined as

$$\frac{i\lambda_I}{3\sqrt{3}} = \langle A_3\uparrow | \hat{H}_{so} | A_2\uparrow \rangle \stackrel{(7)}{=} -\langle A_3\downarrow | \hat{H}_{so} | A_2\downarrow \rangle. \quad (13a)$$

The numerical factor $1/3\sqrt{3}$ is a matter of convention; adding it here, the low-energy expansion of the Bloch transform of $\mathcal{H}_{D_{6h}}$ becomes simpler. In the above formula and also below, we identify a lattice site m with a π state $|X_m\rangle$ residing on it. Since each site hosts one π -orbital state, this assignment is unique. Moreover, since $|A_2\uparrow\rangle = \Sigma_d^{xz} |B_3\downarrow\rangle$, and $|A_3\uparrow\rangle = \Sigma_d^{xz} |B_2\downarrow\rangle$, see Fig. 1, we can write

$$\begin{aligned} \frac{i\lambda_I}{3\sqrt{3}} &= \langle A_3\uparrow | \hat{H}_{so} | A_2\uparrow \rangle \stackrel{(1d)}{=} \langle \Sigma_d^{xz} [B_2\downarrow] | \hat{H}_{so} | \Sigma_d^{xz} [B_3\downarrow] \rangle \\ &\stackrel{(3)}{=} \langle B_2\downarrow | \hat{H}_{so} | B_3\downarrow \rangle \stackrel{(7)}{=} -\langle B_2\uparrow | \hat{H}_{so} | B_3\uparrow \rangle. \end{aligned} \quad (13b)$$

All the sublattice and spin related sign factors are captured in the prefactor term $v_{m,n} [\hat{s}_z]_{\sigma\sigma}$, i.e.,

$$\langle X_m\sigma | \hat{H}_{so} | X_n\sigma \rangle = v_{m,n} [\hat{s}_z]_{\sigma\sigma} \frac{i\lambda_I}{3\sqrt{3}}. \quad (14)$$

There, $v_{m,n} = +1(-1)$, if the next-nearest-neighbor hopping $n \rightarrow m$ via a common neighbor on the opposite sublattice is counter clockwise (clockwise), e.g., for $A_2 \rightarrow (B_1) \rightarrow A_3$, $v_{A_3A_2} = +1$, while for $B_3 \rightarrow (A_1) \rightarrow B_2$, $v_{B_2B_3} = -1$, see Fig. 1. The dependence on spin σ is governed by $[\hat{s}_z]_{\sigma\sigma}$; as defined $[\hat{s}_z]_{\pm\pm} = \pm 1$.

To see the effect of the intrinsic SOC on the band structure we transform $\mathcal{H}_{D_{6h}}$, Eq. (12), from the local atomic into the Bloch basis, $|X_m\sigma\rangle \mapsto |X_{\mathbf{q}}\sigma\rangle$:

$$|X_{\mathbf{q}}\sigma\rangle = \frac{1}{\sqrt{N_1 N_2}} \sum_{\mathbf{R}_m} e^{i\mathbf{q}\cdot\mathbf{R}_m} |X_m\sigma\rangle. \quad (15)$$

Here, $X = \{A, B\}$ and $\sigma = \{\uparrow, \downarrow\}$, dependent on the sublattice and spin degrees of freedom, respectively, \mathbf{q} is the quasimomentum measured from the center of the hexagonal Brillouin zone (Γ point), $N_1 N_2$ is the number of graphene unit cells in the sample, and \mathbf{R}_m is the lattice vector of the m th cell that hosts the orbital $|X_m\sigma\rangle$. Inserting the above unitary transformation into Eq. (12), we transform $\mathcal{H}_{D_{6h}}$ to the Bloch form, $\mathcal{H}_{D_{6h}} = \sum_{\mathbf{q}} \mathcal{H}_{D_{6h}}(\mathbf{q})$, where

$$\mathcal{H}_{D_{6h}}(\mathbf{q}) = \lambda_I f_I(\mathbf{q}) \sum_{X,\sigma} [\hat{\sigma}_z]_{XX} [\hat{s}_z]_{\sigma\sigma} |X_{\mathbf{q}}\sigma\rangle \langle X_{\mathbf{q}}\sigma|. \quad (16)$$

Here, the Pauli matrix $\hat{\sigma}_z$ acts in the space of sublattices— $[\hat{\sigma}_z]_{AA} = 1 = -[\hat{\sigma}_z]_{BB}$, and $[\hat{\sigma}_z]_{AB} = 0 = [\hat{\sigma}_z]_{BA}$. The intrinsic

structural function $f_I(\mathbf{q})$ reads,

$$f_I(\mathbf{q}) = -\frac{2}{3\sqrt{3}} (\sin \mathbf{q} \cdot \mathbf{R}_1 + \sin \mathbf{q} \cdot \mathbf{R}_2 + \sin \mathbf{q} \cdot \mathbf{R}_3). \quad (17)$$

The lattice vectors \mathbf{R}_α ($\alpha = 1, 2, 3$) can be compactly expressed in terms of the Levi-Civita antisymmetric ϵ symbol and the position vectors of the lattice sites A_1, A_2 , and A_3 as displayed at Fig. 1. Particularly,

$$\mathbf{R}_\alpha = \frac{1}{2} \epsilon_{\alpha\beta\gamma} \overrightarrow{A_\gamma A_\beta} = a_L \left(\cos \frac{2\pi(\alpha-1)}{3}, \sin \frac{2\pi(\alpha-1)}{3} \right), \quad (18)$$

where a_L is the lattice constant; in the case of graphene $a_L = 2.46 \text{ \AA}$.

On the orbital level the electronic band structure of graphene π orbitals is well described by the standard nearest-neighbor Hamiltonian,

$$\mathcal{H}_{\text{orb}} = -t \sum_{\sigma} \sum_{\langle(m,n)\rangle} |X_m\sigma\rangle \langle X_n\sigma|, \quad (19)$$

with $t = 2.6 \text{ eV}$. Transforming it to the Bloch form, we arrive at $\mathcal{H}_{\text{orb}} = \sum_{\mathbf{q}} \mathcal{H}_{\text{orb}}(\mathbf{q})$, where

$$\mathcal{H}_{\text{orb}}(\mathbf{q}) = -t \sum_{\sigma} f_{\text{orb}}(\mathbf{q}) [\hat{s}_0]_{\sigma\sigma} |A_{\mathbf{q}}\sigma\rangle \langle B_{\mathbf{q}}\sigma| + \text{H.c.}, \quad (20)$$

and the orbital structural function is given by

$$f_{\text{orb}}(\mathbf{q}) = (1 + e^{i\mathbf{q}\cdot\mathbf{R}_2} + e^{-i\mathbf{q}\cdot\mathbf{R}_3}); \quad (21)$$

\hat{s}_0 is the identity matrix in spin space.

In what follows, we focus on the low-energy physics near the Dirac points,

$$\pm \mathbf{K} = \pm \frac{4\pi}{3a_L} (1, 0), \quad (22)$$

i.e., we substitute for $\mathbf{q} = \pm \mathbf{K} + \mathbf{k}$ and expand the relevant \mathbf{q} -dependent quantities in \mathbf{k} keeping the first nonzero term. For the above defined structural functions, we particularly get

$$f_I(\pm \mathbf{K} + \mathbf{k}) \simeq \pm 1 \quad (23)$$

and

$$f_{\text{orb}}(\pm \mathbf{K} + \mathbf{k}) \simeq \frac{\sqrt{3}a_L}{2} (\mp k_x - i k_y). \quad (24)$$

Fixing the order $\{|A_{\mathbf{q}}\uparrow\rangle, |A_{\mathbf{q}}\downarrow\rangle, |B_{\mathbf{q}}\uparrow\rangle, |B_{\mathbf{q}}\downarrow\rangle\}$ of the Bloch basis, we arrive at the effective low-energy Hamiltonian in the form

$$\mathcal{H}_{\text{eff}}(\tau \mathbf{K} + \mathbf{k}) = \hbar v_F (\tau k_x \hat{\sigma}_x - k_y \hat{\sigma}_y) \hat{s}_0 + \tau \lambda_I \hat{\sigma}_z \hat{s}_z. \quad (25)$$

Here, $\tau \mathbf{K} = \pm \mathbf{K}$ is the shorthand for the Dirac valleys, $\hat{\sigma}_{x(y)}$ are Pauli matrices in the sublattice space, and $v_F = \sqrt{3}a_L t / 2\hbar$ stands for the Fermi velocity; for example, for graphene $v_F \approx 10^6 \text{ m/s}$.

From the above Bloch representation, we see that $\hat{\sigma}_0 \hat{s}_z$ commutes with \mathcal{H}_{eff} , and hence its eigenstates can be labeled by the spin \uparrow and \downarrow projections along the z spin quantization axis independently of \mathbf{k} . The eigenspectrum of \mathcal{H}_{eff} , dependent on the quasimomentum \mathbf{k} , band index $n = +/- = \text{conduction/valence}$, and spin $\sigma = \{\uparrow, \downarrow\}$, reads

$$\varepsilon_{n,\sigma}(\tau \mathbf{K} + \mathbf{k}) = n \sqrt{\lambda_I^2 + \hbar^2 v_F^2 (k_x^2 + k_y^2)}. \quad (26)$$

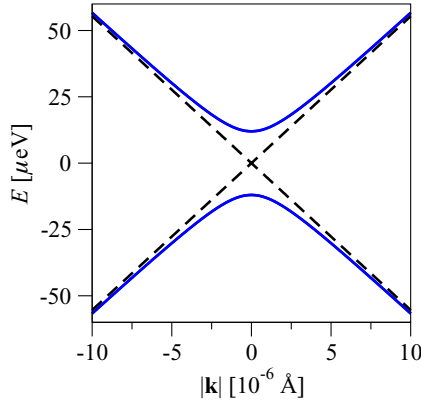


FIG. 2. Electronic band structure of the typical graphenelike system in the vicinity of the Dirac point ($|\mathbf{k}| = 0$) with (solid line) and without (dashed line) the intrinsic (D_{6h} invariant) SOC Hamiltonian. The spectral gap of $2\lambda_I$ and the parabolic shape near $|\mathbf{k}| = 0$ are typical imprints of the intrinsic SOC which does not spin-split the bands.

The corresponding four eigenstates get grouped into pairs, each pair comprising states with the opposite spins, e.g., directly at the $\tau\mathbf{K}$ points, we have two pairs $\{|A_{\tau\mathbf{K}\uparrow}\rangle, |B_{\tau\mathbf{K}\downarrow}\rangle\}$ and $\{|A_{\tau\mathbf{K}\downarrow}\rangle, |B_{\tau\mathbf{K}\uparrow}\rangle\}$, that are split in energy by the intrinsic SOC; spin-orbit interaction opens a spectral gap at the Dirac points. In the case of graphene, the intrinsic gap equals [9] $2\lambda_I \simeq 24 \mu\text{eV}$. The spectral effects of the intrinsic SOC that are imprinted on the band structure are shown at Fig. 2.

B. No-go SOC matrix elements—lethal symmetries

In what follows, we shortly summarize *no-go arguments* showing explicitly how certain SOC mediated matrix elements become inhibited by specific structural symmetries. This will on one hand prove why for pristine graphene only the spin-conserving next-nearest-neighbor coupling λ_I is allowed. On the other hand, by seeing the absence of a particular *no-go symmetry* in the symmetry group of a reduced hexagonal structure we can infer which additional coupling is allowed in the corresponding effective SOC Hamiltonian. We will profit from this insight in the forthcoming sections.

1. Inhibition of all spin-flip SOC—horizontal reflection

Applying horizontal reflection Σ_h^{xy} to a general spin-flip matrix element $\langle X_m\sigma | \hat{H}_{\text{so}} | X_n(-\sigma) \rangle$ between two π states localized on arbitrary lattice sites m and n , we get in accordance with Eq. (1b),

$$\begin{aligned} & \langle X_m\sigma | \hat{H}_{\text{so}} | X_n(-\sigma) \rangle \\ &= \langle i(-1)^{\frac{1-\sigma}{2}} \Sigma_h^{xy} [X_m\sigma] | \hat{H}_{\text{so}} | i(-1)^{\frac{1+\sigma}{2}} \Sigma_h^{xy} [X_n(-\sigma)] \rangle \\ &= -\langle \Sigma_h^{xy} [X_m\sigma] | \hat{H}_{\text{so}} | \Sigma_h^{xy} [X_n(-\sigma)] \rangle \\ &\stackrel{(3)}{=} -\langle X_m\sigma | \hat{H}_{\text{so}} | X_n(-\sigma) \rangle, \end{aligned} \quad (27)$$

what implies that $\langle X_m\sigma | \hat{H}_{\text{so}} | X_n(-\sigma) \rangle = 0$. Hence we showed that the presence of Σ_h^{xy} in the reduced point group inhibits any spin-flip terms in the effective SOC Hamiltonian. If Σ_h^{xy}

would not be present, then we would have a weaker result as discussed below.

2. Inhibition of the nearest-neighbor spin-flip SOC—space inversion, lattice translation, and time reversal

For concreteness, let us focus on the SOC matrix element $\langle A_2\sigma | \hat{H}_{\text{so}} | B_3(-\sigma) \rangle$; see Fig. 1. Employing consecutively space inversion \mathcal{I} , Eq. (1f), unitarity, Eq. (3), and translation by the lattice vector $\vec{a} = \vec{A}_3\vec{A}_2 = \vec{B}_2\vec{B}_3$, Eq. (1g), we get

$$\begin{aligned} \langle A_2\sigma | \hat{H}_{\text{so}} | B_3(-\sigma) \rangle &= \langle -\mathcal{I}[B_2\sigma] | \hat{H}_{\text{so}} | -\mathcal{I}[A_3(-\sigma)] \rangle \\ &= \langle \mathcal{I}[B_2\sigma] | \hat{H}_{\text{so}} | \mathcal{I}[A_3(-\sigma)] \rangle \\ &\stackrel{(3)}{=} \langle B_2\sigma | \hat{H}_{\text{so}} | A_3(-\sigma) \rangle \\ &= \langle T_{\vec{a}}[B_3\sigma] | \hat{H}_{\text{so}} | T_{\vec{a}}[A_2(-\sigma)] \rangle \\ &\stackrel{(3)}{=} \langle B_3\sigma | \hat{H}_{\text{so}} | A_2(-\sigma) \rangle. \end{aligned} \quad (28a)$$

To proceed further, we use the time reversal symmetry, Eq. (5),

$$\langle B_3\sigma | \hat{H}_{\text{so}} | A_2(-\sigma) \rangle \stackrel{(5)}{=} -\langle A_2\sigma | \hat{H}_{\text{so}} | B_3(-\sigma) \rangle. \quad (28b)$$

Combining Eqs. (28a) and (28b), we immediately see that the nearest-neighbor SOC mediated spin-flip hopping $\langle A_2\sigma | \hat{H}_{\text{so}} | B_3(-\sigma) \rangle = 0$. Repeating the same for the remaining neighboring lattice sites at Fig. 1 we inhibit—by the space inversion \mathcal{I} , lattice translation $T_{\vec{a}}$ and time reversal \mathcal{T} —all other nearest-neighbor spin-flip terms in the effective SOC Hamiltonian.

3. Inhibition of the nearest-neighbor spin-conserving SOC—vertical reflection and lattice translation

By similar reasoning as above, we can show that the SOC matrix element $\langle A_2\sigma | \hat{H}_{\text{so}} | B_3\sigma \rangle$ is zero whenever lattice translation $T_{\vec{a}}$ and vertical reflection Σ_v^{yz} are present. Translation by the lattice vector $\vec{a} = \vec{A}_2\vec{A}_3 = \vec{B}_3\vec{B}_2$ implies

$$\begin{aligned} \langle A_2\sigma | \hat{H}_{\text{so}} | B_3\sigma \rangle &= \langle T_{\vec{a}}[A_3\sigma] | \hat{H}_{\text{so}} | T_{\vec{a}}[B_2\sigma] \rangle \\ &\stackrel{(3)}{=} \langle A_3\sigma | \hat{H}_{\text{so}} | B_2\sigma \rangle. \end{aligned} \quad (29a)$$

Moreover, using the vertical reflection, Eq. (1c), we have $|A_3\sigma\rangle = -i\Sigma_v^{yz}|A_2(-\sigma)\rangle$ and $|B_2\sigma\rangle = -i\Sigma_v^{yz}|B_3(-\sigma)\rangle$ and therefore, by unitarity, Eq. (3), we arrive at

$$\langle A_3\sigma | \hat{H}_{\text{so}} | B_2\sigma \rangle = \langle A_2(-\sigma) | \hat{H}_{\text{so}} | B_3(-\sigma) \rangle. \quad (29b)$$

So the last two equations together with Eq. (7) imply

$$\begin{aligned} \langle A_2\sigma | \hat{H}_{\text{so}} | B_3\sigma \rangle &= \langle A_2(-\sigma) | \hat{H}_{\text{so}} | B_3(-\sigma) \rangle \\ &\stackrel{(7)}{=} -\langle A_2\sigma | \hat{H}_{\text{so}} | B_3\sigma \rangle, \end{aligned} \quad (29c)$$

which means that the nearest-neighbor spin-conserving hopping $\langle A_2\sigma | \hat{H}_{\text{so}} | B_3\sigma \rangle$ is zero. Repeating the same argumentation for the other neighboring sites we eliminate—by lattice translation $T_{\vec{a}}$ and vertical reflection Σ_v^{yz} —all remaining nearest-neighbor spin-conserving SOC terms.

The *no-go arguments* based on the horizontal and vertical reflections $\Sigma_h^{xy}, \Sigma_v^{yz} \in D_{6h}$, see Eqs. (27) and (29), explain straightforwardly why the translationally invariant SOC Hamiltonian $\mathcal{H}_{D_{6h}}$ of pristine graphene, Eq. (12), allows only

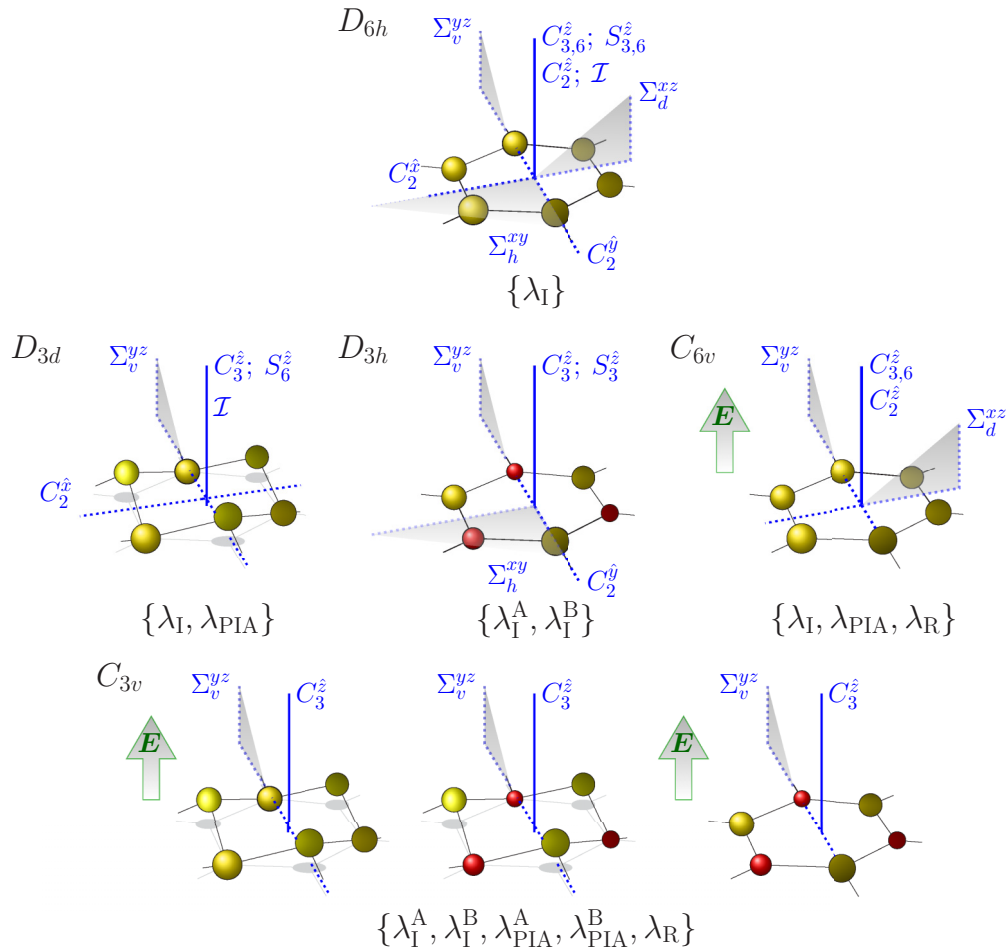


FIG. 3. Point group D_{6h} of pristine graphene (top), its maximal subgroups D_{3d} , D_{3h} , and C_{6v} (second row), and the corresponding symmetry operations (blue symbols). Subgroups D_{3d} , D_{3h} , and C_{6v} are represented, for instance, by graphene mini-ripple, planar boron-nitride and graphene exposed to a transverse external electric field, respectively. They share the common subgroup C_{3v} (third row) what is, for example, the symmetry group (left to right) of graphene mini-ripple in a transverse external electric field, mini-rippled boron-nitride, and boron-nitride in a transverse external electric field. The successive reduction of the point group symmetry (top to bottom) enhances the number of symmetry-allowed SOC parameters, those are summarized in brackets.

the next-nearest-neighbor spin-conserving hoppings. Pristine graphene is an example of a hexagonal system with the highest structural group symmetry. The topic for the next sections are hexagonal systems with lower symmetries—subgroups of the point group D_{6h} . We will start with the maximal structural subgroups D_{3d} , D_{3h} , and C_{6v} —and explore step-by-step the symmetry allowed spin-orbit couplings.

C. Subgroups of D_{6h} —categorization of emergent SOC

Any periodic modification of the pristine hexagonal symmetry reduces the unit cell point group symmetry D_{6h} to one of its subgroups and is manifested by the emergence of new SOC mediated hoppings. The aim of this section is to show a bottom line enabling their classification and categorization.

The minimal structural modifications we will discuss here are (1) *rippling*, (2) *sublattice asymmetry*, and (3) *transverse electric field or substrate* and their mutual combinations, see Fig. 3. We call here a structural modification of the full hexagonal lattice *minimal*, if the reduced point subgroup of D_{6h} experiences minimal modifications in terms of the

number of group elements. Such subgroups are usually called *maximal subgroups*. In the case of D_{6h} , there are in total five maximal subgroups [70]. Each of them has 12 group elements—*group order* 12—which is half of the order of the original point group D_{6h} . Three subgroups— D_{3d} , D_{3h} , and C_{6v} —will be relevant in the present context, while the subgroups D_6 and C_{6h} are irrelevant for us. To be specific, (1) *rippling* reduces $D_{6h} \rightarrow D_{3d}$ what constitutes the point group of graphene miniripple, graphene [82], silicene, and “germanene” [83,84], etc.; (2) *sublattice inversion asymmetry* reduces $D_{6h} \rightarrow D_{3h}$ what is the point group of the planar boron nitride, aluminum nitride, or any other planar system with two nonequivalent interpenetrating triangular lattices A and B ; (3) *transverse electric field* reduces $D_{6h} \rightarrow C_{6v}$ what represents the point group of pristine graphene in an external field or graphene deposited on a substrate that is not breaking the sublattice symmetry. For visualization, summary, and mutual comparison see Fig. 3 and Table I.

It is worth to emphasize that an intersection of any two of D_{3d} , D_{3h} , and C_{6v} is isomorphic [70] to the smaller non-Abelian subgroup $C_{3v} \subset D_{6h}$ with group order 6. This

TABLE I. Point group D_{6h} and its maximal subgroups— D_{3d} , D_{3h} , C_{6v} —including also their common intersection—the point group C_{3v} . For the visualization see Fig. 3. We shortened the notation in terms of the previous definitions: symbol $2C_6^z$ means two sixfold rotations along the z axis, namely, $\mathcal{R}_{\pm\pi/3}^z$, symbol $3C_2'$ stands for three twofold rotations along the axis x , $\mathcal{R}_{\pi/3}^z$, and $\mathcal{R}_{2\pi/3}^z$, respectively, and similarly $3C_2''$ stands for three twofold rotations along the y , $\mathcal{R}_{\pi/3}^z$, and $\mathcal{R}_{2\pi/3}^z$ axis, respectively. By the same logic, $3\Sigma_v$ stands for three mirror reflections in yz , $\mathcal{R}_{\pi/3}^z yz$, and $\mathcal{R}_{2\pi/3}^z yz$ planes, respectively, and so on. If the given set of operations is present/absent in the particular subgroup of D_{6h} , we employ the marker \checkmark / $-$.

Group/Operation	E	$2C_6^z$	$2C_3^z$	C_2^z	$3C_2'$	$3C_2''$	\mathcal{I}	Σ_h	$3\Sigma_v$	$3\Sigma_d$	$2S_3^z$	$2S_6^z$
D_{6h}	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark
D_{3d}	\checkmark	$-$	\checkmark	$-$	\checkmark	$-$	\checkmark	$-$	\checkmark	$-$	$-$	\checkmark
D_{3h}	\checkmark	$-$	\checkmark	$-$	$-$	\checkmark	$-$	\checkmark	\checkmark	$-$	\checkmark	$-$
C_{6v}	\checkmark	\checkmark	\checkmark	\checkmark	$-$	$-$	$-$	$-$	\checkmark	\checkmark	$-$	$-$
C_{3v}	\checkmark	$-$	\checkmark	$-$	$-$	$-$	$-$	$-$	\checkmark	$-$	$-$	$-$

means that an arbitrary combination of two minimal structural modifications leads to the same effective SOC Hamiltonian, which possesses global C_{3v} invariance. For concreteness, graphene miniripple (or graphane, silicene, and germanene) in a transverse electric field— $D_{3d} \cap C_{6v}$ —is from the effective SOC point of view equivalent to a minirippled boron nitride without the field or free standing graphane [$D_{3d} \cap D_{3h}$].

With respect to the structural minimality the point groups D_{3d} , D_{3h} , and C_{6v} can be considered as equivalent since they are all maximal subgroups of D_{6h} . Despite of that minimal subgroup similarity, D_{3d} , D_{3h} , and C_{6v} are different since they result in different SOC phenomena.

1. D_{3d} case: λ_I and λ_{PIA} couplings

Rippled structures such as graphane, silicene, and graphene miniripple—point group D_{3d} —remain invariant under the space inversion \mathcal{I} and time reversal \mathcal{T} , and hence SOC can not cause band spin splittings. The reasoning is finger counting [2]; for any band index n , we have

$$\varepsilon_{n,\sigma}(\mathbf{k}) \stackrel{\mathcal{I}}{=} \varepsilon_{n,-\sigma}(-\mathbf{k}) \stackrel{\mathcal{T}}{=} \varepsilon_{n,-\sigma}(\mathbf{k}). \quad (30)$$

Space inversion \mathcal{I} and vertical reflection Σ_v^{yz} belong to D_{3d} , but the horizontal reflection Σ_h^{xy} does not. Then, according to the *no-go arguments* presented in Sec. III B, the D_{3d} symmetric and time reversal invariant SOC Hamiltonian based on π orbitals allows only next-nearest-neighbor hoppings. The nearest-neighbor SOC is inhibited—the spin-conserving ones by Σ_v^{yz} and spin-flipping by \mathcal{I} . Because \mathcal{I} interchanges sublattices, $|A_i\sigma\rangle = -\mathcal{I}|B_i\sigma\rangle$, see Fig. 1 and Eq. (1f), the next-nearest hoppings should not be sublattice resolved. Indeed,

$$\langle A_i\sigma|\hat{H}_{so}|A_j\sigma'\rangle \stackrel{(3)}{=} \langle B_i\sigma|\hat{H}_{so}|B_j\sigma'\rangle. \quad (31)$$

Similarly, \mathcal{T} interchanges the spin components,

$$\begin{aligned} &\langle X_m\sigma|\hat{H}_{so}|X_n\sigma'\rangle \\ &\stackrel{(5)}{=} -(-1)^{\frac{\sigma+\sigma'}{2}} \langle X_n(-\sigma')|\hat{H}_{so}|X_m(-\sigma)\rangle, \end{aligned} \quad (32)$$

and hence there is only one purely imaginary spin-conserving hopping, say, defined for $\sigma' = \sigma = \uparrow$, and one spin-flipping hopping defined for $\sigma' = -\sigma = \downarrow$, respectively.

It is now a convention—by analogy with the plain graphene—to call the spin-conserving next-nearest-neighbor SOC matrix element intrinsic. Hence also in the D_{3d} case we

adopt the term intrinsic SOC. We define intrinsic $i\lambda_I$ by the same prescription as already given by Eq. (13):

$$\frac{i\lambda_I}{3\sqrt{3}} = \langle A_3\uparrow|\hat{H}_{so}|A_2\uparrow\rangle = \langle B_2\downarrow|\hat{H}_{so}|B_3\downarrow\rangle. \quad (33)$$

The related sublattice-spin sign factors are governed by the prefactor $\nu_{m,n}[\hat{s}_z]_{\sigma\sigma}$ as discussed above.

There is no terminological consensus on how to call the spin-flipping next-nearest-neighbor SOC matrix element. Such a term already emerged in bilayer graphene [86], but that time its group symmetry origin was not discussed. Later, when studying SOC effects in semi-hydrogenated graphene (graphane) the acronym PIA—a shorthand for the “pseudospin inversion asymmetry” was proposed [34]. In that case, the pseudospin was explicitly broken by the hydrogenation of one sublattice resulting in the C_{3v} invariant structure. Unfortunately, the pseudospin asymmetry is not supported by the point group D_{3d} which contains the space inversion \mathcal{I} . So the former PIA acronym is not fully appropriate in D_{3d} case. Alternatively, authors of Ref. [77] used the term “intrinsic Rashba SOC.” This is also inappropriate, since normally the Rashba [87] SOC causes band splittings and this is also not the case in D_{3d} invariant systems.

The emergence of the spin-flipping next-nearest-neighbor SOC is related to the absence of the horizontal reflection Σ_h^{xy} in the underlying point group (see also other cases discussed below). Since the horizontal plane is a principal mirror plane of the structure we can call it “principal plane mirror asymmetry” induced SOC, preserving the subscript PIA (by explicitly breaking with abbreviation rule). Thus the PIA spin-orbit coupling λ_{PIA} can be defined as

$$\frac{2}{3}\lambda_{PIA} \equiv \langle A_3\uparrow|\hat{H}_{so}|A_2\downarrow\rangle \stackrel{(5)}{=} -\langle A_2\uparrow|\hat{H}_{so}|A_3\downarrow\rangle. \quad (34)$$

Again, the numerical prefactor $2/3$ is a matter of convenience. Employing the vertical reflection $\Sigma_v^{yz} \in D_{3d}$ we show that λ_{PIA} is purely real

$$\begin{aligned} &\langle A_3\uparrow|\hat{H}_{so}|A_2\downarrow\rangle \stackrel{(1c)}{=} \langle -i\Sigma_v^{yz}[A_2\downarrow]|\hat{H}_{so}| -i\Sigma_v^{yz}[A_3\uparrow]\rangle \\ &\stackrel{(3)}{=} \langle A_2\downarrow|\hat{H}_{so}|A_3\uparrow\rangle = \overline{\langle A_3\uparrow|\hat{H}_{so}|A_2\downarrow\rangle}. \end{aligned} \quad (35)$$

As a consequence of the last two equations, we have the practical identity:

$$\frac{2}{3}\lambda_{\text{PIA}} = \langle A_3\uparrow | \hat{H}_{\text{so}} | A_2\downarrow \rangle = -\langle A_3\downarrow | \hat{H}_{\text{so}} | A_2\uparrow \rangle. \quad (36)$$

The remaining next-nearest-neighbor spin flipping SOC's on the A -sublattice, see Fig. 1, can be connected with λ_{PIA} by rotations $\mathcal{R}_{\pm\frac{2\pi}{3}}^z \in D_{3d}$. In particular, we get

$$\begin{aligned} \langle A_1\uparrow | \hat{H}_{\text{so}} | A_3\downarrow \rangle &\stackrel{(1a)}{=} e^{-i\frac{2\pi}{3}} \langle \mathcal{R}_{\frac{2\pi}{3}}^z [A_3\uparrow] | \hat{H}_{\text{so}} | \mathcal{R}_{\frac{2\pi}{3}}^z [A_2\downarrow] \rangle \\ &\stackrel{(3)}{=} e^{-i\frac{2\pi}{3}} \frac{2}{3}\lambda_{\text{PIA}}, \end{aligned} \quad (37)$$

$$\begin{aligned} \langle A_2\uparrow | \hat{H}_{\text{so}} | A_1\downarrow \rangle &\stackrel{(1a)}{=} e^{i\frac{2\pi}{3}} \langle \mathcal{R}_{-\frac{2\pi}{3}}^z [A_3\uparrow] | \hat{H}_{\text{so}} | \mathcal{R}_{-\frac{2\pi}{3}}^z [A_2\downarrow] \rangle \\ &\stackrel{(3)}{=} e^{i\frac{2\pi}{3}} \frac{2}{3}\lambda_{\text{PIA}}. \end{aligned} \quad (38)$$

The SOC matrix elements on the sublattice B can be obtained from the above A -sublattice formulas after employing the space inversion. The spin-flipping next-nearest-neighbor SOC elements for both sublattices can be compactly summarized by the following formula¹

$$\langle X_m\sigma | \hat{H}_{\text{so}} | X_n\sigma' \rangle = [\hat{\sigma}_z]_{XX} [i\hat{s} \times \mathbf{d}_{m,n}]_{\sigma\sigma'} \frac{2}{3}\lambda_{\text{PIA}}, \quad (39)$$

where $\mathbf{d}_{m,n} = \overrightarrow{mn} / |\overrightarrow{mn}|$ is the unit vector in the horizontal (xy) plane pointing from the lattice site n to the next-nearest-neighbor site m ; \hat{s} stands for the array of Pauli matrices and spin projections $\sigma \neq \sigma'$.

To summarize, the effective translationally invariant SOC Hamiltonian based on π orbitals that respects D_{3d} symmetry and time reversal is given by

$$\begin{aligned} \mathcal{H}_{D_{3d}} &= \frac{i\lambda_I}{3\sqrt{3}} \sum_{\sigma} \sum_{\langle\langle m,n \rangle\rangle} v_{m,n} [\hat{s}_z]_{\sigma\sigma'} |X_m\sigma\rangle \langle X_n\sigma| \\ &+ \frac{2\lambda_{\text{PIA}}}{3} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle m,n \rangle\rangle} [\hat{\sigma}_z]_{XX} [i\hat{s} \times \mathbf{d}_{m,n}]_{\sigma\sigma'} |X_m\sigma\rangle \langle X_n\sigma'|. \end{aligned} \quad (40)$$

Transforming the above SOC Hamiltonian into the Bloch form, $\mathcal{H}_{D_{3d}} = \sum_{\mathbf{q}} \mathcal{H}_{D_{3d}}(\mathbf{q})$, we arrive at

$$\begin{aligned} \mathcal{H}_{D_{3d}}(\mathbf{q}) &= \sum_{X,\sigma,\sigma'} [\hat{\sigma}_z]_{XX} \{ \lambda_I f_1(\mathbf{q}) [\hat{s}_z]_{\sigma\sigma'} + \lambda_{\text{PIA}} f_P(\mathbf{q}) [\hat{s}_+]_{\sigma\sigma'} \\ &+ \lambda_{\text{PIA}} \overline{f_P(\mathbf{q})} [\hat{s}_-]_{\sigma\sigma'} \} |X_{\mathbf{q}}\sigma\rangle \langle X_{\mathbf{q}}\sigma'|, \end{aligned} \quad (41)$$

where the structural SOC function $f_1(\mathbf{q})$ is given by Eq. (17) and $f_P(\mathbf{q})$ is defined as follows

$$f_P(\mathbf{q}) = \frac{4i}{3} (\sin \mathbf{q} \cdot \mathbf{R}_1 + e^{-i\frac{2\pi}{3}} \sin \mathbf{q} \cdot \mathbf{R}_2 + e^{+i\frac{2\pi}{3}} \sin \mathbf{q} \cdot \mathbf{R}_3). \quad (42)$$

¹Space inversion interchanges sublattices, $[\hat{\sigma}_z]_{\mathcal{I}(X)\mathcal{I}(X)} = -[\hat{\sigma}_z]_{XX}$, and as well the orientation of connecting \mathbf{d} -vector, $\mathbf{d}_{\mathcal{I}(m)\mathcal{I}(n)} = -\mathbf{d}_{m,n}$, so in total both sign changes compensate in agreement with Eq. (31).

A direct inspection shows that the quasimomentum dependent spin operator (in units of $\hbar/2$)

$$\text{Spin}(\mathbf{q}) = \hat{\sigma}_0 \left[f_P(\mathbf{q}) \hat{s}_+ + \overline{f_P(\mathbf{q})} \hat{s}_- + \frac{\lambda_I}{\lambda_{\text{PIA}}} f_1(\mathbf{q}) \hat{s}_z \right] \quad (43)$$

commutes with $\mathcal{H}_{D_{3d}}(\mathbf{q})$. Since the orbital Hamiltonian is diagonal in spin space, the eigenstates of $H_{\text{orb}}(\mathbf{q}) + \mathcal{H}_{D_{3d}}(\mathbf{q})$ can be chosen as ‘‘spin-up’’ and ‘‘spin-down’’ states with respect to the momentum dependent quantization axis specified by the unit vector:

$$\mathbf{n}(\mathbf{q}) = \frac{(\text{Re}[f_P(\mathbf{q})], -\text{Im}[f_P(\mathbf{q})], \frac{\lambda_I}{\lambda_{\text{PIA}}} f_1(\mathbf{q}))}{\sqrt{|f_P(\mathbf{q})|^2 + \frac{\lambda_I^2}{\lambda_{\text{PIA}}^2} |f_1(\mathbf{q})|^2}}. \quad (44)$$

Consequently, $\text{Spin}(\mathbf{q}) \simeq \hat{\sigma}_0[\mathbf{n}(\mathbf{q}) \cdot \hat{s}]$. It is clear that at the time-invariant momenta, i.e., at Γ and M points, $\mathbf{n}(\mathbf{q})$ is not well-defined. Hence there is not a well-defined global map from the full first Brillouin zone ($2d$ torus) into the $2d$ sphere, $\mathbf{q} \mapsto \mathbf{n}(\mathbf{q})$, and thus not a well-defined global winding number. Expanding $f_P(\mathbf{q})$ around the Dirac points, $\mathbf{q} = \tau\mathbf{K} + \mathbf{k}$, keeping the first appearing nonzero terms, we get

$$f_P(\tau\mathbf{K} + \mathbf{k}) \simeq -(ik_x + k_y)a_L, \quad (45)$$

where a_L stands for the lattice constant. Then the effective D_{3d} -invariant low-energy Hamiltonian around $\tau\mathbf{K}$ valley that includes both orbital and SOC terms is given by

$$\begin{aligned} \mathcal{H}_{\text{eff}}(\tau\mathbf{K} + \mathbf{k}) &= \hbar v_F (\tau k_x \hat{\sigma}_x - k_y \hat{\sigma}_y) \hat{s}_0 + \tau \lambda_I \hat{\sigma}_z \hat{s}_z \\ &+ \lambda_{\text{PIA}} \hat{\sigma}_z (k_x \hat{s}_y - k_y \hat{s}_x) a_L. \end{aligned} \quad (46)$$

Correspondingly, the momentum dependent spin quantization axis is aligned along the unit vector,

$$\mathbf{n}(\tau\mathbf{K} + \mathbf{k}) = \frac{(-k_y a_L, k_x a_L, \tau \frac{\lambda_I}{\lambda_{\text{PIA}}})}{\sqrt{(k_x^2 + k_y^2) a_L^2 + \frac{\lambda_I^2}{\lambda_{\text{PIA}}^2}}}. \quad (47)$$

The eigenspectrum of $\mathcal{H}_{\text{eff}}(\tau\mathbf{K} + \mathbf{k})$ —labeled by quasimomentum \mathbf{k} , band index $n = \pm$ and spin σ with respect to $\mathbf{n}(\tau\mathbf{K} + \mathbf{k})$ —reads

$$\varepsilon_{n,\sigma}(\tau\mathbf{K} + \mathbf{k}) = n \sqrt{\lambda_I^2 + (\hbar^2 v_F^2 + \lambda_{\text{PIA}}^2 a_L^2) (k_x^2 + k_y^2)}, \quad (48)$$

so the states are indeed spin degenerate as we already noticed in Eq. (30). The effect of λ_{PIA} SOC is twofold. First, looking at the eigenspectrum, λ_{PIA} effectively renormalizes the Fermi velocity $v_F \rightarrow \sqrt{v_F^2 + \lambda_{\text{PIA}}^2 a_L^2 / \hbar^2}$, or equivalently in terms of the orbital nearest-neighbor hopping $t \rightarrow \sqrt{t^2 + 4\lambda_{\text{PIA}}^2 / 3}$. In situations when the strength of orbital hopping t substantially exceeds the strength of λ_{PIA} this effect is expected to be marginal, e.g., in silicene [77] $t \simeq 1.1$ eV and $\lambda_{\text{PIA}} \simeq 0.7$ meV, however, in germanene [77], $t \simeq 0.9$ eV and $\lambda_{\text{PIA}} \simeq 10.7$ meV and hence the renormalization of the orbital hopping should be more pronounced. Second, λ_{PIA} introduces a nontrivial spin-orbit field in the k space, $\mathbf{n}(\mathbf{q}) \cdot \hat{s}$, that gives rise to the in plane component of the spin-expectation value, see Fig. 4.

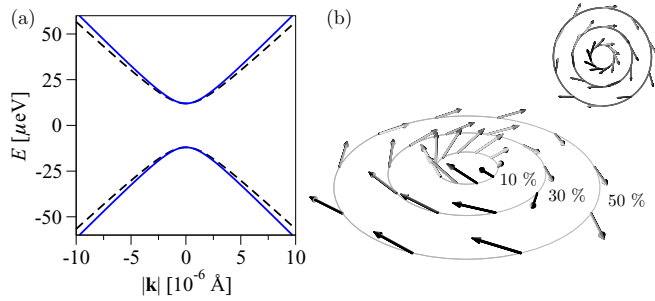


FIG. 4. Electronic band structure and spin-orbit field around the K -point in the presence of D_{3d} invariant SOC Hamiltonian. (a) Electronic band structure for $t = 2.6$ eV, $\lambda_1 = 12$ μeV , and $\lambda_{\text{PIA}} = 0.1$ eV (black dashed) and $\lambda_{\text{PIA}} = 1$ eV (blue solid), respectively, showing the effect of renormalization of Fermi velocity. (b) D_{3d} spin-orbit field around the Dirac point along the circles with radius 10%, 30%, and 50% of $\overline{\text{KM}}$ -distance for $t = 2.6$ eV, $\lambda_1 = 12$ μeV , and $\lambda_{\text{PIA}} = 60$ μeV . The inset shows a top view of the spin-orbit field. The circular low-energy symmetry changes to the triangular one and the z component of the spin-orbit field becomes suppressed when moving away from the Dirac point.

2. D_{3h} case: λ_1^A and λ_1^B couplings

Hexagonal boron nitride is a prototype of a planar hexagonal structure that consists of two nonequivalent interpenetrating triangular lattices—in our particular example, composed of borons and nitrogens, respectively. Since the horizontal reflection Σ_h^{xy} belongs to D_{3h} , spin-flipping SOC mediated hoppings are not allowed according to the *no-go argument* (see Sec. III B 1). Similarly, the vertical mirror reflection Σ_v^{yz} belongs to D_{3h} and hence by the assertion (see Sec. III B 3) there are neither spin-conserving nearest-neighbor SOC terms only. The broken sublattice symmetry can not further constrain the intrinsic SOC terms and hence they become sublattice dependent, i.e., $\lambda_1^A \neq \lambda_1^B$. Motivated by the previous analysis and knowing that they are purely imaginary we define them via the formulas

$$\frac{i\lambda_1^A}{3\sqrt{3}} = \langle A_3 \uparrow | \hat{H}_{\text{so}} | A_2 \uparrow \rangle, \quad (49)$$

$$\frac{i\lambda_1^B}{3\sqrt{3}} = \langle B_2 \downarrow | \hat{H}_{\text{so}} | B_3 \downarrow \rangle; \quad (50)$$

for the atomic sites configuration see Fig. 1. In analogy with Eq. (12), the D_{3h} invariant SOC Hamiltonian reads

$$\begin{aligned} \mathcal{H}_{D_{3h}} = & \frac{i\lambda_1^A}{3\sqrt{3}} \sum_{\sigma} \sum_{\langle\langle m,n \rangle\rangle} v_{m,n} [\hat{s}_z]_{\sigma\sigma} |A_m \sigma\rangle \langle A_n \sigma| \\ & + \frac{i\lambda_1^B}{3\sqrt{3}} \sum_{\sigma} \sum_{\langle\langle m,n \rangle\rangle} v_{m,n} [\hat{s}_z]_{\sigma\sigma} |B_m \sigma\rangle \langle B_n \sigma|. \end{aligned} \quad (51)$$

Contrary to the D_{6h} case, the lack of space inversion symmetry \mathcal{I} in D_{3h} —hence two different values of λ_1^A and λ_1^B —causes spin splitting of the band structure, see Fig. 5.

The low-energy Bloch representation of $\mathcal{H}_{\text{orb}}(\tau\mathbf{K} + \mathbf{k}) + \mathcal{H}_{D_{3h}}(\tau\mathbf{K} + \mathbf{k})$ can be easily deduced from Eq. (25) when properly substituting λ_1 by its sublattice resolved counterparts

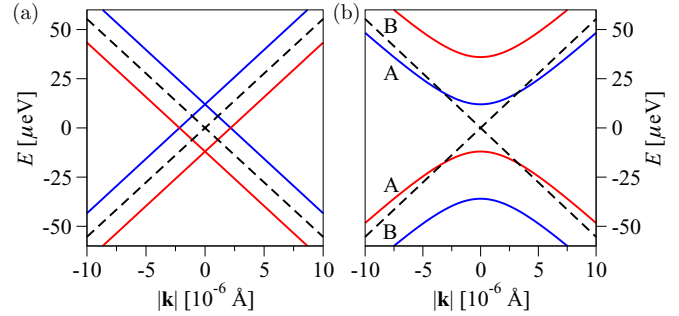


FIG. 5. Electronic band structure around the K -point in the presence of D_{3h} invariant SOC Hamiltonian without staggered potential Δ : for $t = 2.6$ eV and $\lambda_1^A = 12$ μeV and (a) $\lambda_1^B = -\lambda_1^A$ and (b) $\lambda_1^B = 3\lambda_1^A$. Blue and red lines indicate bands with up and down spin projections, respectively. Label A or B at the given band indicates which sublattice is dominantly occupied by electronic states at that band, assuming their momenta are close to the Dirac point. For comparison, the black dashed lines display the energy dispersion of the pristine graphene without SOC and the staggered Δ .

λ_1^A and λ_1^B . The result is as follows:

$$\begin{aligned} \mathcal{H}_{\text{eff}}(\tau\mathbf{K} + \mathbf{k}) = & \hbar v_F (\tau k_x \hat{\sigma}_x - k_y \hat{\sigma}_y) \hat{s}_0 + \Delta \hat{\sigma}_z \hat{s}_0 \\ & + \frac{\tau}{2} [\lambda_1^A (\hat{\sigma}_z + \hat{\sigma}_0) + \lambda_1^B (\hat{\sigma}_z - \hat{\sigma}_0)] \hat{s}_z. \end{aligned} \quad (52)$$

Contrary to the previous cases, the broken sublattice symmetry allows also a new term in the orbital Hamiltonian \mathcal{H}_{orb} —the second term in the first line parameterized by the so called staggered potential Δ . The two inequivalent sublattices can possess different on-site energies and their difference equals 2Δ . Similarly as in the D_{6h} case, the spin operator $\hat{\sigma}_0 \hat{s}_z$ commutes with \mathcal{H}_{eff} allowing us to label its eigenstates with the spin up and spin down entries. The eigenspectrum of $\mathcal{H}_{\text{eff}}(\tau\mathbf{K} + \mathbf{k})$ —labeled by the quasimomentum \mathbf{k} , conduction/valence band index $n = +/-$ and spin $\sigma = \{\uparrow, \downarrow\} = \{+1, -1\}$ with respect to \hat{s}_z reads

$$\begin{aligned} \varepsilon_{n,\sigma}(\tau\mathbf{K} + \mathbf{k}) = & \frac{\sigma}{2} (\lambda_1^A - \lambda_1^B) \\ & + n \sqrt{\left[\Delta + \frac{\sigma}{2} (\lambda_1^A + \lambda_1^B) \right]^2 + \hbar^2 v_F^2 (k_x^2 + k_y^2)}. \end{aligned} \quad (53)$$

The band structure visualization of the SOC induced splittings in the presence of staggered Δ are displayed in Fig. 6. Direct analysis of Eq. (53) shows that there are two distinct spectral cases—an insulating (gapped) and a band-inverted (gapless) one. The criteria to get spectral band-inversion are $\text{sign } \lambda_1^A \neq \text{sign } \lambda_1^B$ and $|\Delta| < \max(|\lambda_1^A|, |\lambda_1^B|)$.

3. C_{6v} case: λ_B , λ_R , and λ_{PIA} couplings

Graphene in an external transverse electric field or graphene disposed on a substrate is a prototype of the structure with C_{6v} structural symmetry. In this case the sublattices remain equivalent—the rotation $\mathcal{R}_{\pi/3}^z$ that interchanges them belongs to the point group. However, we lose all the structural symmetries flipping the orientation of the transverse z -axis. According to the arguments in Sec. III B, lack of space

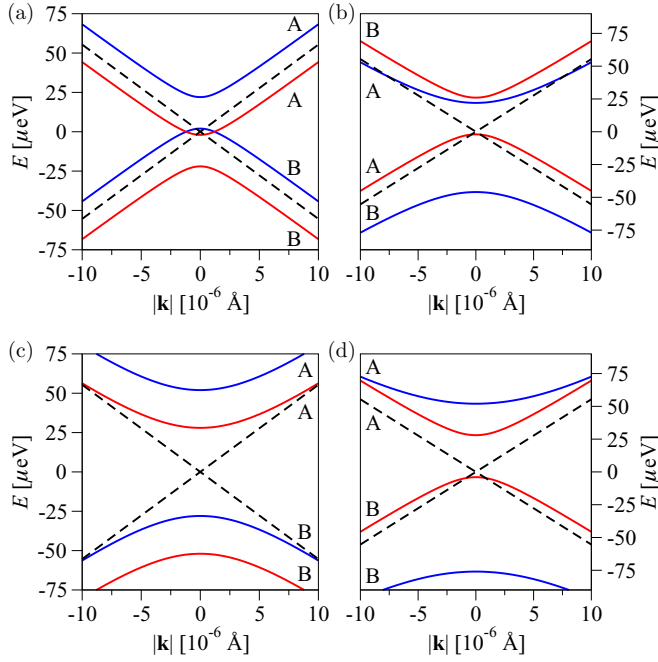


FIG. 6. Electronic band structure around the K -point in the presence of D_{3h} invariant SOC Hamiltonian and staggered potential Δ for $t = 2.6$ eV and $\lambda_1^A = 12$ μ eV and (a) $\lambda_1^B = -\lambda_1^A$ and $\Delta = 10$ μ eV, (b) $\lambda_1^B = 3\lambda_1^A$ and $\Delta = 10$ μ eV, (c) $\lambda_1^B = -\lambda_1^A$ and $\Delta = 40$ μ eV, and (d) $\lambda_1^B = 3\lambda_1^A$ and $\Delta = 40$ μ eV, respectively. For $\text{sign}\lambda_1^A \neq \text{sign}\lambda_1^B$, the increased value of the staggered potential drives the band-inverted structure (a) to the insulating one (c). Blue and red lines indicate bands with up and down spin projections, respectively, and the dashed lines display the orbital band structure of pristine graphene. Label A or B at the given band indicates which sublattice is dominantly occupied by electronic states at that band, assuming their momenta are close to the Dirac point.

inversion \mathcal{I} and horizontal reflection Σ_h^{xy} can not prevent the system from spin-flip SOC hoppings among nearest- and next-nearest neighbors. Contrary to that, Σ_v^{yz} inhibits the spin-conserving nearest-neighbor SOCs, but allows intrinsic—next-nearest-neighbor—SOCs. From this finger counting symmetry analysis and the *no-go arguments* we know that the C_{6v} invariant SOC Hamiltonian would potentially host three couplings: λ_1 and λ_{PIA} —the terms analogous with the already discussed D_{3d} case, see Eq. (33) and (34)—and the new spin-flipping term λ_R acting between the nearest neighbors. Conventionally the latter is called Rashba SOC [88] and in terms of a SOC matrix element it can be defined as follows,

$$\frac{2}{3}i\lambda_R \equiv \langle A_2\uparrow | \hat{H}_{\text{so}} | B_3\downarrow \rangle \stackrel{(5)}{=} -\langle B_3\uparrow | \hat{H}_{\text{so}} | A_2\downarrow \rangle. \quad (54)$$

In the above definition we have already employed the purely imaginary character of the coupling. Applying the dihedral reflection Σ_d^{xz} to the defining matrix element we obtain,

$$\begin{aligned} \langle A_2\uparrow | \hat{H}_{\text{so}} | B_3\downarrow \rangle &= \langle \Sigma_d^{xz} [B_3\downarrow] | \hat{H}_{\text{so}} | -\Sigma_d^{xz} [A_2\uparrow] \rangle \\ &\stackrel{(3)}{=} -\langle B_3\downarrow | \hat{H}_{\text{so}} | A_2\uparrow \rangle = -\overline{\langle A_2\uparrow | \hat{H}_{\text{so}} | B_3\downarrow \rangle}, \end{aligned} \quad (55)$$

what is indeed what we wanted to show. In analogy with Eq. (39) we can also write a compact formula for any nearest-neighbor spin-flipping matrix element,

$$\langle X_m \sigma | \hat{H}_{\text{so}} | X'_n \sigma' \rangle = [\hat{s} \times \mathbf{d}_{m,n}]_{\sigma\sigma'} \frac{2}{3}i\lambda_R, \quad (56)$$

where, $\mathbf{d}_{m,n} = \overrightarrow{mn} / |\overrightarrow{mn}|$ is the unit vector in the horizontal (xy) plane pointing from lattice site n to nearest-neighbor site m and $\sigma \neq \sigma'$, and X and X' refer to the opposite sublattices.

Let us emphasize that contrary to D_{3d} case the point group C_{6v} lacks space inversion. Therefore the PIA analogs of Eq. (31) in C_{6v} case reads

$$\begin{aligned} \langle A_i\sigma | \hat{H}_{\text{so}} | A_j\sigma' \rangle &\stackrel{(1a)}{=} \langle e^{i\frac{\pi}{2}\sigma} \mathcal{R}_\pi^z [B_i\sigma] | \hat{H}_{\text{so}} | e^{i\frac{\pi}{2}\sigma'} \mathcal{R}_\pi^z [B_j\sigma'] \rangle \\ &\stackrel{(3)}{=} e^{i\frac{\pi}{2}(\sigma'-\sigma)} \langle B_i\sigma | \hat{H}_{\text{so}} | B_j\sigma' \rangle = -\langle B_i\sigma | \hat{H}_{\text{so}} | B_j\sigma' \rangle, \end{aligned} \quad (57)$$

and the analog of (39) is as follows:

$$\langle X_m \sigma | \hat{H}_{\text{so}} | X_n \sigma' \rangle = [i\hat{s} \times \mathbf{d}_{m,n}]_{\sigma\sigma'} \frac{2}{3} \lambda_{\text{PIA}}. \quad (58)$$

So the general C_{6v} invariant SOC Hamiltonian based on π -states, time reversal and translational invariance reads,

$$\begin{aligned} \mathcal{H}_{C_{6v}} &= \frac{i\lambda_1}{3\sqrt{3}} \sum_{\sigma} \sum_{\langle\langle m,n \rangle\rangle} v_{m,n} [\hat{s}_z]_{\sigma\sigma} |X_m \sigma\rangle \langle X_n \sigma| \\ &+ \frac{2\lambda_{\text{PIA}}}{3} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle m,n \rangle\rangle} [i\hat{s} \times \mathbf{d}_{m,n}]_{\sigma\sigma'} |X_m \sigma\rangle \langle X_n \sigma'| \\ &+ \frac{2i\lambda_R}{3} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle m,n \rangle\rangle} [\hat{s} \times \mathbf{d}_{m,n}]_{\sigma\sigma'} |X_m \sigma\rangle \langle X_n \sigma'|. \end{aligned} \quad (59)$$

The first and the last term in $\mathcal{H}_{C_{6v}}$ are the well known SOC terms from the seminal papers of Kane and Mele [32,88]. However, the staggered potential Δ added and considered by them in the orbital part [see Eq. (1) in Ref. [88]] is in fact not compatible with the C_{6v} symmetry, but rather the C_{3v} one discussed in the next section. What is more striking is the presence of the second— λ_{PIA} SOC term—which seems to be generally overseen by the community. Readers can easily convince themselves that there are not enough symmetries in C_{6v} that can cancel its appearance in $\mathcal{H}_{C_{6v}}$. Indeed, to map the real matrix element $\langle A_3\uparrow | \hat{H}_{\text{so}} | A_2\downarrow \rangle \sim \lambda_{\text{PIA}}$, Eq. (34), to “ \pm itself” within the pool of C_{6v} symmetries, one can use respectively the vertical, Σ_v^{yz} , and dihedral, Σ_d^{xz} , reflections—both flip spins—and accompany them by the rotation \mathcal{R}_π^z , see Figs. 1 and 3. Since $\mathcal{R}_\pi^z = \Sigma_v^{yz} \circ \Sigma_d^{xz}$, the composition $\mathcal{S} = \mathcal{R}_\pi^z \circ \Sigma_d^{xz} \circ \Sigma_v^{yz}$ is the identity in the orbital and also in the spin space and hence $\mathcal{S} : |A_i \sigma\rangle \rightarrow |A_i \sigma\rangle$. So at the end $\langle A_3\uparrow | \hat{H}_{\text{so}} | A_2\downarrow \rangle = +\langle A_3\uparrow | \hat{H}_{\text{so}} | A_2\downarrow \rangle$ what gives no constraint on λ_{PIA} .

The first (intrinsic) SOC term in $\mathcal{H}_{C_{6v}}$, Eq. (59)—as we have discussed earlier—is not causing SOC splitting of the electronic band structure. The band SOC splitting is solely due to the space inversion breaking term—Rashba SOC λ_R , that is accompanied by the principal-plane mirror asymmetry term—PIA SOC λ_{PIA} . One can anticipate this fact either directly from eigenspectrum (discussed below) or from the generally valid argument of Bychkov and Rashba [87]. They showed that a SOC induced band spin-splitting would appear in systems with a single high-symmetry (at least three-fold) axis, in our case

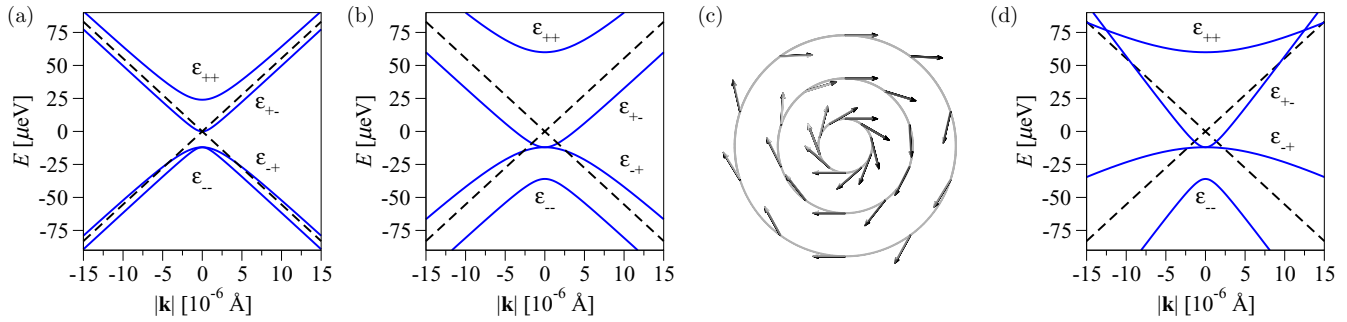


FIG. 7. Electronic band structure and spin-orbit field around the K -point in the presence of C_{6v} invariant SOC Hamiltonian for fixed $t = 2.6$ eV and $\lambda_I = 12$ μ eV, and different values of λ_R and λ_{PIA} SOC parameters. In panel (a) $\lambda_R = 6$ μ eV $<$ λ_I (gapped) and $\lambda_{PIA} = 0$; in panel (b) $\lambda_R = 24$ μ eV $>$ λ_I (gapless) and $\lambda_{PIA} = 0$. Panel (c) displays the spin-orbit field $\mathbf{n}(\mathbf{q})$ around K -point for the energy band ε_{--} in figure (b), circles radii correspond to 10%, 30% and 50% of \overline{KM} -distance. In panel (d) $\lambda_R = 24$ μ eV $>$ λ_I (gapless) and $\lambda_{PIA} = 1$ eV, a non-zero value of λ_{PIA} renormalizes the Fermi velocities v_F of different spin-split sub-bands $\varepsilon_{n,n'}(\mathbf{K} + \mathbf{k})$. For $\Omega > 0$, see Eq. (66), λ_{PIA} causes a band crossing in the conduction (displayed case) or valence band. For comparison, the black dashed lines display the energy dispersion of the pristine graphene without SOC.

the transverse z -axis, and an invariant vector along this axis, in our case the transverse electric field or the outward direction from the surface, what is exactly the case of C_{6v} group and its subgroups.

In what follows we transform the C_{6v} -invariant SOC Hamiltonian into the Bloch form, $\mathcal{H}_{C_{6v}} = \sum_{\mathbf{q}} \mathcal{H}_{C_{6v}}(\mathbf{q})$. The intrinsic term in $\mathcal{H}_{C_{6v}}(\mathbf{q})$ is identical with $\mathcal{H}_{D_{6h}}(\mathbf{q})$, see Eq. (16), the PIA term entering $\mathcal{H}_{C_{6v}}(\mathbf{q})$ can be deduced from the corresponding term in $\mathcal{H}_{D_{3d}}(\mathbf{q})$, Eq. (41), omitting there $[\hat{\sigma}_z]_{XX}$. For that reason we write here explicitly only the Rashba part

$$\begin{aligned} \mathcal{H}_R(\mathbf{q}) = & i\lambda_R \sum_{\sigma,\sigma'} \sum_{X,X'} \{ [\hat{\sigma}_+]_{XX'} (f_R(\mathbf{q}) [\hat{s}_+]_{\sigma\sigma'}) \\ & + \overline{f_R(-\mathbf{q})} [\hat{s}_-]_{\sigma\sigma'} - [\hat{\sigma}_-]_{XX'} \overline{f_R(\mathbf{q})} [\hat{s}_-]_{\sigma\sigma'} \\ & + \overline{f_R(-\mathbf{q})} [\hat{s}_+]_{\sigma\sigma'} \} |X_{\mathbf{q}} \sigma\rangle \langle X'_{\mathbf{q}} \sigma'|. \end{aligned} \quad (60)$$

The Rashba SOC structural function is given as follows,

$$f_R(\mathbf{q}) = \frac{2}{3} \{ 1 + e^{-i\frac{2\pi}{3}} e^{-i\mathbf{q}\cdot\mathbf{R}_3} + e^{i\frac{2\pi}{3}} e^{i\mathbf{q}\cdot\mathbf{R}_2} \}, \quad (61)$$

and the sublattice raising/lowering operators are defined by $\hat{\sigma}_{\pm} = \frac{1}{2}(\hat{\sigma}_x \pm i\hat{\sigma}_y)$. In our sublattice convention we particularly have $[\hat{\sigma}_+]_{AB} = 1 = [\hat{\sigma}_-]_{BA}$ and $[\hat{\sigma}_+]_{BA} = 0 = [\hat{\sigma}_-]_{AB}$. It is worth to mention that there does not exist a simple SOC field $\mathbf{n}(\mathbf{q}) \cdot \hat{s}$ such that the operator $\hat{\sigma}_0[\mathbf{n}(\mathbf{q}) \cdot \hat{s}]$ commutes with $\mathcal{H}_{C_{6v}}(\mathbf{q})$.

The low energy expansion $f_R(\tau\mathbf{K} + \mathbf{k})$ to the first order in \mathbf{k} can be summarized by,

$$f_R(\tau\mathbf{K} + \mathbf{k}) = \begin{cases} 2 + i\frac{2}{\sqrt{3}}k_y a_L & \text{for } +\mathbf{K}, \\ -\frac{1}{\sqrt{3}}k_x a_L - i\frac{1}{\sqrt{3}}k_y a_L & \text{for } -\mathbf{K}. \end{cases} \quad (62)$$

Since Rashba SOC is off-diagonal in spin and sublattice spaces, it is common to approximate $f_R(\tau\mathbf{K} + \mathbf{k})$ by $f_R(\tau\mathbf{K})$. Doing so we get the effective C_{6v} -invariant low energy Hamiltonian,

$$\begin{aligned} \mathcal{H}_{\text{eff}}(\tau\mathbf{K} + \mathbf{k}) = & \hbar v_F (\tau k_x \hat{\sigma}_x - k_y \hat{\sigma}_y) \hat{s}_0 + \tau \lambda_I \hat{\sigma}_z \hat{s}_z \\ & + \lambda_{PIA} \hat{\sigma}_0 (k_x \hat{s}_y - k_y \hat{s}_x) a_L - \lambda_R (\tau \hat{\sigma}_x \hat{s}_y + \hat{\sigma}_y \hat{s}_x). \end{aligned} \quad (63)$$

whose eigenspectrum labeled by $n = \pm$ and $n' = \pm$ reads,

$$\begin{aligned} \varepsilon_{n,n'}(\tau\mathbf{K} + \mathbf{k}) \\ = n' \lambda_R + n \sqrt{(\lambda_I + n' \lambda_R)^2 + (\hbar v_F - n' \lambda_{PIA} a_L)^2 (k_x^2 + k_y^2)}. \end{aligned} \quad (64)$$

Similarly as before, \mathbf{k} is the quasi-momentum measured with respect to the given $\tau\mathbf{K}$ -valley, $n = \pm$ stands for the conduction and valence bands, respectively, and the index $n' = \pm$ stands for the spin polarization. The spin expectation value—spin-orbit field $\mathbf{n}(\mathbf{q})$ —at the given \mathbf{q} and the band indices n and n' can be computed from the normalized eigenstates $|\mathbf{q}, n, n'\rangle$ via $\mathbf{n}(\mathbf{q}) = \langle \mathbf{q}, n, n' | \hat{s} | \mathbf{q}, n, n' \rangle$. The general formula is too complex and therefore we present only a result for the low energy eigenstates $|\tau\mathbf{K} + \mathbf{k}, n, n'\rangle$ of Eq. (63) around the $\tau\mathbf{K}$ -valley:

$$\begin{pmatrix} \langle \hat{s}_x \rangle \\ \langle \hat{s}_y \rangle \\ \langle \hat{s}_z \rangle \end{pmatrix} = \alpha_{n,n'} \cdot \beta_{n'} \begin{pmatrix} -n' k_y / k \\ +n' k_x / k \\ 0 \end{pmatrix}. \quad (65)$$

Here $\alpha_{n,n'} = \text{sign}(\tau\lambda_I + 2n'\lambda_R - \varepsilon_{n,n'})$, $\beta_{n'} = \text{sign}(\hbar v_F - n'\lambda_{PIA} a_L)$, $k = \sqrt{k_x^2 + k_y^2}$, and $\varepsilon_{n,n'}$ stands as a shorthand for eigenenergy $\varepsilon_{n,n'}(\tau\mathbf{K} + \mathbf{k})$, see Eq. (64). For the visualization of the band structure and the spin-orbit field texture see Fig. 7. It is worth to emphasize that at the Dirac points the two eigenvalues out of four become always degenerate. For example, for $\lambda_I > \lambda_R > 0$ we have $\varepsilon_{-,-}(\tau\mathbf{K}) = \varepsilon_{-+}(\tau\mathbf{K}) = -\lambda_I$ for the valence bands, and $\varepsilon_{+,+}(\tau\mathbf{K}) = \lambda_I \mp 2\lambda_R$ for conduction ones; the spectrum possesses SOC induced gap with value $2(\lambda_I - \lambda_R)$. For $\lambda_R > \lambda_I > 0$ we have $\varepsilon_{-,-}(\tau\mathbf{K}) = \varepsilon_{-+}(\tau\mathbf{K}) = -\lambda_I$, i.e. one valence and one conduction bands touch each other, and hence the spectral gap closes, the two remaining bands are starting from energies $\varepsilon_{\mp,-}(\tau\mathbf{K}) = \mp 2\lambda_R + \lambda_I$. The case $\lambda_I = \lambda_R > 0$ is critical, the spectrum changes from the gaped to gapless and we have a triple degeneracy $\varepsilon_{-,-}(\tau\mathbf{K}) = \varepsilon_{-+}(\tau\mathbf{K}) = \varepsilon_{+,-}(\tau\mathbf{K}) = -\lambda_I$. Moving away from the Dirac points the PIA SOC starts to manifest, see Eq. (64). For the given band index n the two spin split branches $n' = \pm$ with energies $\varepsilon_{n,\pm}(\tau\mathbf{K} + \mathbf{k})$ possess different Fermi velocities

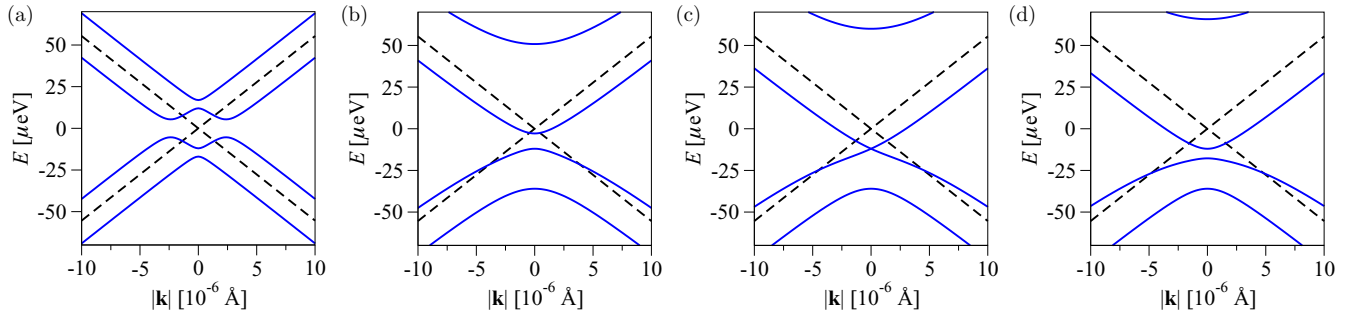


FIG. 8. Electronic band structure around the K -point in the presence of C_{3v} invariant SOC Hamiltonian for fixed $t = 2.6$ eV, staggered potential $\Delta = 0$ and $\lambda_I^A = 12$ μeV , and different values of SOC parameters. In panel (a) $\lambda_I^B = -\lambda_I^A$ and $\lambda_R = 6$ μeV , the band inversion from Fig. 5(a) is lifted due to presence of finite Rashba SOC λ_R . In panels (b)–(d) $\lambda_I^B = 3\lambda_I^A$, gradually growing λ_R , 6 $\mu\text{eV} < \sqrt{2}\lambda_I^A < 20$ μeV , drives the trivial band structure displayed at Fig. 5(b) from gapped (b) to gapless (c) and gapped again (d). For comparison, the black dashed lines display the energy dispersion of the pristine graphene without SOC.

$v_{F\pm} = \sqrt{v_F^2 \mp \lambda_{\text{PIA}}^2 a_L^2 / \hbar^2}$. If Ω , defined as follows

$$\Omega = 1 + 2 \frac{\lambda_I}{\lambda_R} \frac{\lambda_{\text{PIA}} a_L}{\hbar v_F} + \left(\frac{\lambda_{\text{PIA}} a_L}{\hbar v_F} \right)^2 \approx 1 + 2 \frac{\lambda_I}{\lambda_R} \frac{\lambda_{\text{PIA}} a_L}{\hbar v_F}, \quad (66)$$

is greater than zero, the two spin-split bands $\varepsilon_{n,\pm}(\tau\mathbf{K} + \mathbf{k})$ cross along a circle in k -space with a center at $\tau\mathbf{K}$ and radius

$$k_{\text{cr}} = \left| \frac{\lambda_R}{\lambda_{\text{PIA}} a_L} \sqrt{\Omega} \right| \approx \left| \frac{\lambda_R}{\lambda_{\text{PIA}} a_L} + \frac{\lambda_I}{\hbar v_F} \right|. \quad (67)$$

It depends on the relative signs of the entering SOC parameters whether this crossing appears for the valence ($n = -1$) or conduction bands ($n = +1$), see Fig. 7. However, for realistic graphenelike values of orbital and SOC parameters $k_{\text{cr}} \approx 1/a_L$, what is far away from the Dirac valleys, and beyond the applicability of linear approximation.

Let us conclude by comparing the spin-orbit characteristics of systems with C_{6v} and D_{3d} point group symmetries. Both

of them host principal-plane mirror asymmetry induced SOC coupling λ_{PIA} , but only D_{3d} simultaneously contain space-inversion symmetry \mathcal{I} , see Fig. 3. This seems to be crucial for answering the question whether PIA SOC causes spin splitting. It does in the absence of the space inversion— C_{6v} case, Eq. (64)—however, it does not in D_{3d} case, Eq. (48).

4. C_{3v} case: sublattice resolved λ_I 's and λ_{PIA} 's couplings, and λ_R

The point group $C_{3v} = \{E, 2C_3, 3\sigma_v\}$ is a subgroup of all three structural groups we have discussed earlier. For example, compared to the previous C_{6v} case, the point group C_{3v} lacks all the symmetries interchanging the sublattices. Hence the translationally invariant SOC Hamiltonian based on π orbitals with C_{3v} and time reversal symmetries can be derived from the Hamiltonian $\mathcal{H}_{C_{6v}}$, Eq. (59), making the next-nearest-neighbor SOC hoppings $i\lambda_I$ and λ_{PIA} sublattice dependent, i.e., $i\lambda_I \rightarrow \{i\lambda_I^A, i\lambda_I^B\}$ and $\lambda_{\text{PIA}} \rightarrow \{\lambda_{\text{PIA}}^A, \lambda_{\text{PIA}}^B\}$:

$$\begin{aligned} \mathcal{H}_{C_{3v}} = & \frac{i\lambda_I^A}{3\sqrt{3}} \sum_{\sigma} \sum_{\langle\langle m,n \rangle\rangle} v_{m,n} [\hat{s}_z]_{\sigma\sigma'} |A_m\sigma\rangle \langle A_n\sigma| + \frac{i\lambda_I^B}{3\sqrt{3}} \sum_{\sigma} \sum_{\langle\langle m,n \rangle\rangle} v_{m,n} [\hat{s}_z]_{\sigma\sigma'} |B_m\sigma\rangle \langle B_n\sigma| \\ & + \frac{2\lambda_{\text{PIA}}^A}{3} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle m,n \rangle\rangle} [i\hat{\mathbf{s}} \times \mathbf{d}_{m,n}]_{\sigma\sigma'} |A_m\sigma\rangle \langle A_n\sigma'| + \frac{2\lambda_{\text{PIA}}^B}{3} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle m,n \rangle\rangle} [i\hat{\mathbf{s}} \times \mathbf{d}_{m,n}]_{\sigma\sigma'} |B_m\sigma\rangle \langle B_n\sigma'| \\ & + \frac{2i\lambda_R}{3} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle m,n \rangle\rangle} [\hat{\mathbf{s}} \times \mathbf{d}_{m,n}]_{\sigma\sigma'} |X_m\sigma\rangle \langle X_n\sigma'|. \end{aligned} \quad (68)$$

This Hamiltonian governs SOC effects in systems with broken sublattice symmetry (an effective staggered potential) and the fixed transverse direction (substrate or transverse electric field). Examples of such systems are semihydrogenated graphene [34] (graphone), graphene/TMDC heterostructures [52,53], silicene on the substrate etc. For the visualization, see Fig. 8.

The Bloch form of the Hamiltonian $\mathcal{H}_{C_{3v}}$, Eq. (68), is straightforward since all the structural functions— $f_I(\mathbf{q})$, $f_P(\mathbf{q})$, $f_R(\mathbf{q})$ —were already given. Instead of that we fix the order of the Bloch basis $\{|A_q\uparrow\rangle, |A_q\downarrow\rangle, |B_q\uparrow\rangle, |B_q\downarrow\rangle\}$ and provide the low-energy Hamiltonian around $\mathbf{q} = \tau\mathbf{K} + \mathbf{k}$, including the orbital term with the staggered potential, $\mathcal{H}_{\text{orb}}(\tau\mathbf{K} + \mathbf{k}) = \hbar v_F(\tau k_x \hat{\sigma}_x - k_y \hat{\sigma}_y) \hat{\sigma}_0 + \Delta \hat{\sigma}_z \hat{\sigma}_0$, in the matrix form

$$\mathcal{H}_{\text{eff}}(\tau\mathbf{K} + \mathbf{k}) = \begin{pmatrix} \tau\lambda_I^A + \Delta & -\lambda_{\text{PIA}}^A (ik_x + k_y) a_L & \hbar v_F(\tau k_x + ik_y) & 2i\lambda_R \delta_{\tau\mathbf{K},+\mathbf{K}} \\ -\lambda_{\text{PIA}}^A (-ik_x + k_y) a_L & -\tau\lambda_I^A + \Delta & 2i\lambda_R \delta_{\tau\mathbf{K},-\mathbf{K}} & \hbar v_F(\tau k_x + ik_y) \\ \hbar v_F(\tau k_x - ik_y) & -2i\lambda_R \delta_{\tau\mathbf{K},-\mathbf{K}} & -\tau\lambda_I^B - \Delta & -\lambda_{\text{PIA}}^B (ik_x + k_y) a_L \\ -2i\lambda_R \delta_{\tau\mathbf{K},+\mathbf{K}} & \hbar v_F(\tau k_x - ik_y) & -\lambda_{\text{PIA}}^B (-ik_x + k_y) a_L & \tau\lambda_I^B - \Delta \end{pmatrix}. \quad (69)$$

IV. SYSTEMS IN ABSENCE OF TRANSLATIONAL INVARIANCE—IMPURITY INDUCED SOC HAMILTONIANS

In the forthcoming sections, we discuss effective SOC Hamiltonians for hexagonal systems in the presence of locally chemisorbed impurities focusing on light adatoms and simple admolecules. The case of physisorbed heavy adatoms is discussed in Refs. [40,58]. Since translational invariance is lost, the invariant expansion and decomposition into the irreps at high-symmetry points in the Brillouin zone are not applicable. However, the tight-binding-like methodology based on the local atomic orbitals and their group symmetry properties allows us to treat this problem very naturally. We assume a dilute coverage by light adsorbates and hence it is enough to investigate local SOC effects due to a single chemisorbed impurity—cluster formation and interference SOC effects among nearby impurity centers are therefore not discussed.

The electronic structure of an adatom and host (in most cases graphene) and the underlying molecular dynamics determine mainly three stable binding positions: the *hollow*, *top*, and *bridge* one. Equivalently, we can distinguish those adatom configurations through their local point group symmetries: C_{6v} for the hollow, C_{3v} for the top, and C_{2v} for the bridge one. For simplicity, we treat the chemisorbed adatom as monovalent, i.e., it bonds via a single effective orbital that is invariant under the local point-group symmetries. This monovalency assumption seems to be crude, though experience shows that the effective single-orbital description works very well [34–37]. However, an extension to the multiorbital case is technically straightforward.

As already stated, we are interested in local effective SOC Hamiltonians in the presence of an impurity, that are invariant under the corresponding local point group symmetries. Those can be then added to the global translational invariant Hamiltonians of the host systems as discussed in the previous sections. Locality for us means hoppings up to the next-nearest neighbors with respect to the adsorbed element. In what follows, we will label the adatom by O and the corresponding atomic orbital by $|O\rangle$. Similarly, the adatom nearest-neighbor sites and orbitals will be denoted by Y_j and $|Y_j\rangle$, respectively, and the next-nearest ones by Z_j and $|Z_j\rangle$. The number of nearest and next-nearest carbon neighbors may vary depending on the adsorption configuration—this is indicated by the subscript j .

From the orbital point of view the minimal tight-binding description of the adatom that chemisorbs with its nearest neighbors is given by the Hamiltonian [25,34–37,89] \mathcal{H}_{orb} , which is defined as

$$\mathcal{H}_{\text{orb}} = \omega \sum_{\sigma} \sum_{\langle O, Y_j \rangle} |O\sigma\rangle \langle Y_j\sigma| + |Y_j\sigma\rangle \langle O\sigma| + \varepsilon \sum_{\sigma} |O\sigma\rangle \langle O\sigma|. \quad (70)$$

The first term describes a hybridization ω between the adatom and its nearest neighbors (summation over $\langle O, Y_j \rangle$) and the second represents the adatom's on-site energy. For the remaining orbitals, we assume in the minimal-model scenario zero on-site contributions. The above orbital Hamiltonian is applicable to the hollow, top, and bridge configu-

TABLE II. Orbital tight-binding parameters for different adatoms: hydrogen, fluorine, methyl, and copper in top and bridge position [34–37].

Adatom/model parameters (eV)	ω	ε
Hydrogen (top) [34]	7.50	0.16
Fluorine (top) [35]	5.50	-2.20
Methyl (top) [36]	7.60	-0.19
Copper (top) [37]	0.81	0.08
Copper (bridge) [37]	0.54	0.02

ration, respectively. The representative values of the orbital model parameters for different adatoms are summarized in Table II.

A. Adatom in hollow position

Ab initio studies are unveiling that light metallic adatoms [90] from groups I-III and also heavy transition metals [40,90,91] favor to adsorb above the centers of graphene hexagons, i.e., at the hollow positions. The same is true for light admolecules like NH_3 , H_2O , and NO_2 [92]. The situation is schematically shown in Fig. 9. The central adatom O has six nearest carbon neighbors Y_j and since the out-of plane position of the adatom fixes the orientation of the perpendicular z axis the structure is locally described by the point group C_{6v} . We will focus on a SOC Hamiltonian including the adatom orbital $|O\rangle$ and the π -state carbon orbitals $|Y_j\rangle$ of its direct nearest neighbors only. We first discuss the SOC mediated hoppings among Y 's sites and then we account for hoppings between the adatom orbital $|O\rangle$ and its six neighboring orbitals $|Y_j\rangle$. Since the translational symmetry is lost, we avoid using attributes like intrinsic, Rashba, and so on for the local SOC mediated hoppings. Instead we use the full taxonomy: spin-conserving (next) nearest-neighbor hopping $\Lambda_c^{(n)n}$ and spin-flipping (next) nearest-neighbor hopping $\Lambda_f^{(n)n}$, respectively, reserving for the local SOC capital Λ .

The translationally invariant SOC Hamiltonian with C_{6v} symmetry was discussed in the preceding section, Eq. (59). Making it local, the global terms— $i\lambda_I$, λ_{PIA} , and $i\lambda_R$ —can not diminish. They would be respectively recast into their local analogs— $i\Lambda_c^{\text{nn}}$, Λ_f^{nn} , and $i\Lambda_f^{\text{n}}$. Since all the Y 's sites are equivalent, there are not sublattice resolved partners of those Λ 's. In addition, the lack of the translational invariance allows now also the purely imaginary spin-conserving nearest-neighbor hopping $i\Lambda_c^{\text{n}} \simeq \langle Y_i\sigma | \hat{H}_{\text{so}} | Y_{i+1}\sigma \rangle$; see no-go arguments of Sec. III B. So finally, there are four independent

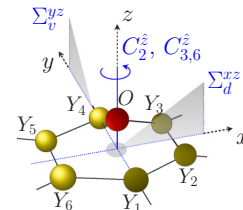


FIG. 9. Adatom bonded in the hollow position: local point group symmetry C_{6v} —similar to graphene in the transverse external electric field, atom labeling convention, axes orientations, and C_{6v} group operations as discussed in the text.

SOC mediated hoppings among the Y 's sites, which—in analogy with the former analysis—can be defined as follows:

$$i\Lambda_c^{\text{nn}} = \langle Y_5 \uparrow | \hat{H}_{\text{so}} | Y_3 \uparrow \rangle, \quad (71a)$$

$$\Lambda_f^{\text{nn}} = \langle Y_5 \uparrow | \hat{H}_{\text{so}} | Y_3 \downarrow \rangle, \quad (71b)$$

$$i\Lambda_f^{\text{n}} = \langle Y_3 \uparrow | \hat{H}_{\text{so}} | Y_2 \downarrow \rangle, \quad (71c)$$

$$i\Lambda_c^{\text{n}} = \langle Y_2 \uparrow | \hat{H}_{\text{so}} | Y_3 \uparrow \rangle; \quad (71d)$$

for the labeling of atomic sites see Fig. 9. Here we no longer use the numerical prefactors $1/3\sqrt{3}$ and $2/3$, which were convenient for the low-energy k -space expansions. The SOC mediated hoppings among the Y sites at different configurations can be obtained by Eqs. (5), (14), and (56). For $i\Lambda_c^{\text{n}}$, we have in analogy with Eq. (14) the following identity which holds for any two nearest neighbors Y_j and Y_k of the adatom O :

$$\langle Y_j \sigma | \hat{H}_{\text{so}} | Y_k \sigma \rangle = \tilde{\nu}_{Y_j, Y_k} [\hat{s}_z]_{\sigma\sigma} i\Lambda_c^{\text{n}}. \quad (72)$$

Here, $\tilde{\nu}_{Y_j, Y_k} = +1(-1)$ if the hopping from the site Y_k to Y_j via a central adatom O is counter clockwise (clockwise).

Next, we examine SOC mediated hoppings between the adatom orbital $|O\rangle$ and its neighbors $|Y_j\rangle$ along the hexagonal ring. For that it is enough to look at matrix elements $\langle O \uparrow | \hat{H}_{\text{so}} | Y_1 \uparrow \rangle$ and $\langle O \uparrow | \hat{H}_{\text{so}} | Y_1 \downarrow \rangle$, respectively. Assuming $|O\rangle$ is C_{6v} and time reversal invariant—i.e., $S|O\rangle = |O\rangle$ for any $S \in C_{6v}$ and $\mathcal{T}|O\rangle = |O\rangle$ as would be the case of alkali metals—we can show that the first of the above matrix elements is identically zero and the second is purely imaginary. Particularly,

$$\begin{aligned} \langle O \uparrow | \hat{H}_{\text{so}} | Y_1 \uparrow \rangle &\stackrel{(1c)}{=} \langle -i\Sigma_v^{yz} [O \downarrow] | \hat{H}_{\text{so}} | -i\Sigma_v^{yz} [Y_1 \downarrow] \rangle \\ &\stackrel{(3)}{=} \langle O \downarrow | \hat{H}_{\text{so}} | Y_1 \downarrow \rangle \stackrel{(7)}{=} -\langle O \uparrow | \hat{H}_{\text{so}} | Y_1 \uparrow \rangle. \end{aligned} \quad (73)$$

For the spin-flip hopping, we get

$$\begin{aligned} \langle O \uparrow | \hat{H}_{\text{so}} | Y_1 \downarrow \rangle &\stackrel{(1c)}{=} \langle -i\Sigma_v^{yz} [O \downarrow] | \hat{H}_{\text{so}} | -i\Sigma_v^{yz} [Y_1 \uparrow] \rangle \\ &\stackrel{(3)}{=} \langle O \downarrow | \hat{H}_{\text{so}} | Y_1 \uparrow \rangle \stackrel{(5)}{=} -\langle O \uparrow | \hat{H}_{\text{so}} | Y_1 \downarrow \rangle, \end{aligned} \quad (74)$$

what allows us to define the SOC term,

$$i\Lambda_f^{\text{On}} = \langle O \uparrow | \hat{H}_{\text{so}} | Y_1 \downarrow \rangle. \quad (75)$$

Equivalent couplings can be specified by reflections, rotations and time reversal, e.g., by applying $\mathcal{R}_{\frac{2}{3}}$, we get

$$\begin{aligned} \langle O \uparrow | \hat{H}_{\text{so}} | Y_2 \downarrow \rangle &= \langle e^{i\frac{\pi}{6}} \mathcal{R}_{\frac{2}{3}} [O \uparrow] | \hat{H}_{\text{so}} | e^{-i\frac{\pi}{6}} \mathcal{R}_{\frac{2}{3}} [Y_1 \downarrow] \rangle \\ &\stackrel{(3)}{=} e^{-i\frac{\pi}{3}} \langle O \uparrow | \hat{H}_{\text{so}} | Y_1 \downarrow \rangle \stackrel{(71)}{=} e^{-i\frac{\pi}{3}} i\Lambda_f^{\text{On}}, \end{aligned} \quad (76)$$

and in general, for any Y_j and $\sigma \neq \sigma'$, we have

$$\langle O \sigma | \hat{H}_{\text{so}} | Y_j \sigma' \rangle = [\hat{\mathbf{s}} \times \mathbf{d}_{O, Y_j}]_{\sigma\sigma'} i\Lambda_f^{\text{On}}, \quad (77)$$

where the meaning of \mathbf{d}_{O, Y_j} is identical as before—a unit vector in xy plane pointing from site Y_j to O . The local SOC Hamiltonian for the hollow position possesses five SOC terms— $i\Lambda_c^{\text{n}}$, $i\Lambda_c^{\text{nn}}$, $i\Lambda_f^{\text{n}}$, Λ_f^{nn} , and $i\Lambda_f^{\text{On}}$ —and is given as

follows:

$$\begin{aligned} \mathcal{H}_{\text{so}}^{\text{hol}} &= i\Lambda_c^{\text{n}} \sum_{\sigma} \sum_{\langle Y_j, Y_k \rangle} \tilde{\nu}_{Y_j, Y_k} [\hat{s}_z]_{\sigma\sigma} |Y_j \sigma\rangle \langle Y_k \sigma| \\ &+ i\Lambda_c^{\text{nn}} \sum_{\sigma} \sum_{\langle\langle Y_j, Y_k \rangle\rangle} \nu_{Y_j, Y_k} [\hat{s}_z]_{\sigma\sigma} |Y_j \sigma\rangle \langle Y_k \sigma| \\ &+ i\Lambda_f^{\text{n}} \sum_{\sigma \neq \sigma'} \sum_{\langle Y_j, Y_k \rangle} [\hat{\mathbf{s}} \times \mathbf{d}_{Y_j, Y_k}]_{\sigma\sigma'} |Y_j \sigma\rangle \langle Y_k \sigma'| \\ &+ \Lambda_f^{\text{nn}} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle Y_j, Y_k \rangle\rangle} [\hat{\mathbf{s}} \times \mathbf{d}_{Y_j, Y_k}]_{\sigma\sigma'} |Y_j \sigma\rangle \langle Y_k \sigma'| \\ &+ i\Lambda_f^{\text{On}} \sum_{\sigma \neq \sigma'} \sum_{\langle O, Y_j \rangle} [\hat{\mathbf{s}} \times \mathbf{d}_{O, Y_j}]_{\sigma\sigma'} |O \sigma\rangle \langle Y_j \sigma'| + \text{H.c.} \end{aligned} \quad (78)$$

Again, the summation over the nearest- and next-nearest neighbors is specified by \langle, \rangle and $\langle\langle, \rangle\rangle$ brackets, respectively; for the atomic configurations that enter ν , $\tilde{\nu}$, and \mathbf{d} see Fig. 9.

B. Adatom in top position

Adsorption in the top position seems to be favorable for light atoms like hydrogen [34,93], fluorine [35,94,95] and copper [37,96,97], the heavier gold atom [90,97], and, for example, also the light methyl admolecule [36]. The model configuration has a local C_{3v} point group symmetry and is displayed in Fig. 10—an adatom O binding on the top possesses one nearest Y neighbor, three second-nearest Z neighbors, and six third-nearest W neighbors. To compare the global and local C_{3v} cases, which have different centers of symmetry, we consider also mutual SOC hoppings implementing the third-nearest W neighbors.

The local C_{3v} -invariant SOC Hamiltonian accounting for SOC mediated hoppings among the Y , Z , and W carbon sites—the SOC hoppings connecting the adatom will be discussed later—can be naturally derived from the global C_{3v} Hamiltonian, Eq. (68). In analogy with the global $i\lambda_1^A$, $i\lambda_1^B$, λ_{PIA}^A , λ_{PIA}^B , and $i\lambda_R$ couplings, we correspondingly have

$$i\Lambda_c^{\text{YW}} = \langle Y \uparrow | \hat{H}_{\text{so}} | W_3 \uparrow \rangle, \quad (79a)$$

$$i\Lambda_c^{\text{ZZ}} = \langle Z_3 \uparrow | \hat{H}_{\text{so}} | Z_2 \uparrow \rangle, \quad (79b)$$

$$\Lambda_f^{\text{YW}} = \langle Y \uparrow | \hat{H}_{\text{so}} | W_3 \downarrow \rangle, \quad (79c)$$

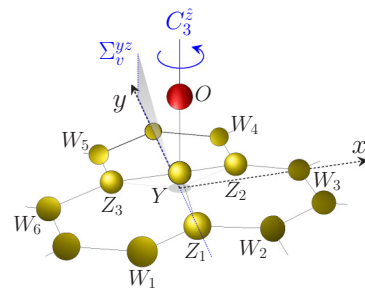


FIG. 10. Adatom bonded in the top position with a center of symmetry on the bonding axis: the local point group symmetry C_{3v} , atom labeling convention, axes orientations, and C_{3v} group operations as discussed in the main text.

$$\Lambda_f^{ZZ} = \langle Z_3 \uparrow | \hat{H}_{so} | Z_2 \downarrow \rangle, \quad (79d)$$

$$i\Lambda_f^{YZ} = \langle Y \uparrow | \hat{H}_{so} | Z_1 \downarrow \rangle. \quad (79e)$$

Here, again the subscripts ‘‘c’’ and ‘‘f’’ stand for spin-conserving and spin-flipping hoppings, respectively, and the superscripts made from Y , Z , and W encode particular nearest- or next-nearest-neighbor hoppings among the Y , Z , and W carbon sites. For atomic configuration and labeling see Fig. 10.

Using Eq. (9), we see that $i\Lambda_c^{YW}$ and $i\Lambda_c^{ZZ}$ —local analogs of $i\lambda_f^A$ and $i\lambda_f^B$ —are purely imaginary. Similarly, substituting in Eq. (35) A_2 by Z_2 and A_3 by Z_3 unveils that Λ_f^{ZZ} —a local analog of λ_{PIA}^B —is purely real. Readapting the argumentation used in Eq. (55) to the situation displayed at Fig. 10, we get

$$\begin{aligned} \langle Y \uparrow | \hat{H}_{so} | Z_1 \downarrow \rangle &= \langle -i \Sigma_v^{yz} [Y \downarrow] | \hat{H}_{so} | -i \Sigma_v^{yz} [Z_1 \uparrow] \rangle \\ &\stackrel{(3)}{=} \langle Y \downarrow | \hat{H}_{so} | Z_1 \uparrow \rangle \stackrel{(5)}{=} -\overline{\langle Y \uparrow | \hat{H}_{so} | Z_1 \downarrow \rangle}, \end{aligned} \quad (80)$$

what confirms that $i\Lambda_f^{YZ}$ —a local analog of $i\lambda_R$ —is purely imaginary.

What differs from the global C_{3v} case is the spin-flip coupling Λ_f^{YW} —an analog of λ_{PIA}^A . Since now the sites Y and W are not interchangeable we cannot use the argument analogous to Eq. (35) and hence Λ_f^{YW} is in general complex. This slightly affects the former phase-factor formula, Eq. (58), which now read

$$\begin{aligned} \langle Y \sigma | \hat{H}_{so} | W_j \sigma' \rangle &= [i \hat{s} \times \mathbf{d}_{Y,W_j}]_{\sigma\sigma'} [\text{Re}(\Lambda_f^{YW}) \\ &+ i \nu_{Y,W_j} \text{Im}(\Lambda_f^{YW})]. \end{aligned} \quad (81)$$

The meaning of \mathbf{d}_{Y,W_j} and ν_{Y,W_j} stays the same as before. The spin-orbit mediated hoppings among the carbon atoms in the vicinity of the impurity site O are now recapped.

In what follows, we discuss the SOC mediated hoppings $\langle O \sigma | \hat{H}_{so} | Y \sigma' \rangle$ and $\langle O \sigma | \hat{H}_{so} | Z_i \sigma' \rangle$ that couple directly to the adatom orbital $|O\rangle$ —assuming it is C_{3v} and time reversal invariant. Repeating the discussion at the end of previous section, see Eqs. (73) and (74), we immediately get

$$i\Lambda_c^{OZ} = \langle O \uparrow | \hat{H}_{so} | Z_1 \uparrow \rangle \equiv 0, \quad (82)$$

$$i\Lambda_f^{OZ} = \langle O \uparrow | \hat{H}_{so} | Z_1 \downarrow \rangle \neq 0. \quad (83)$$

To show that $\langle O \uparrow | \hat{H}_{so} | Y \uparrow \rangle$ and $\langle O \uparrow | \hat{H}_{so} | Y \downarrow \rangle$ are zero one can proceed as follows: for the first term, we have

$$\begin{aligned} \langle O \uparrow | \hat{H}_{so} | Y \uparrow \rangle &\stackrel{(7)}{=} -\langle O \downarrow | \hat{H}_{so} | Y \downarrow \rangle \\ &\stackrel{(1c)}{=} -\langle -i \Sigma_v^{yz} [O \uparrow] | \hat{H}_{so} | -i \Sigma_v^{yz} [Y \uparrow] \rangle \\ &\stackrel{(3)}{=} -\langle O \uparrow | \hat{H}_{so} | Y \uparrow \rangle, \end{aligned} \quad (84)$$

which implies that $\langle O \uparrow | \hat{H}_{so} | Y \uparrow \rangle \equiv 0$. To show that $\langle O \uparrow | \hat{H}_{so} | Y \downarrow \rangle$ is zero, we apply rotations $\mathcal{R}_{\pm \frac{2\pi}{3}}^z \in C_{3v}$, then

$$\begin{aligned} \langle O \uparrow | \hat{H}_{so} | Y \downarrow \rangle &\stackrel{(1a)}{=} \langle e^{\pm i \frac{\pi}{3}} \mathcal{R}_{\pm \frac{2\pi}{3}}^z [O \uparrow] | \hat{H}_{so} | e^{\mp i \frac{\pi}{3}} \mathcal{R}_{\pm \frac{2\pi}{3}}^z [Y \downarrow] \rangle \\ &\stackrel{(3)}{=} e^{\mp i \frac{2\pi}{3}} \langle O \uparrow | \hat{H}_{so} | Y \downarrow \rangle. \end{aligned} \quad (85)$$

The above relation can be fulfilled only by zero, therefore $\langle O \uparrow | \hat{H}_{so} | Y \downarrow \rangle = 0$.

Summarizing Eqs. (79) and (83), we have in total six spin-orbit couplings—four purely imaginary $i\Lambda_c^{YW}$, $i\Lambda_c^{ZZ}$, $i\Lambda_f^{YZ}$, and $i\Lambda_f^{OZ}$, one purely real Λ_f^{ZZ} , and one in general complex Λ_f^{YW} . The local SOC Hamiltonian with C_{3v} symmetry that corresponds to the impurity in the top position reads

$$\begin{aligned} \mathcal{H}_{so}^{\text{top}} &= i\Lambda_c^{YW} \sum_{\sigma} \sum_{\langle\langle Y, W_j \rangle\rangle} \nu_{Y, W_j} [\hat{s}_z]_{\sigma\sigma'} |Y \sigma\rangle \langle W_j \sigma| + \text{H.c.} \\ &+ i\Lambda_c^{ZZ} \sum_{\sigma} \sum_{\langle\langle Z_j, Z_k \rangle\rangle} \nu_{Z_j, Z_k} [\hat{s}_z]_{\sigma\sigma'} |Z_j \sigma\rangle \langle Z_k \sigma| \\ &+ \sum_{\sigma \neq \sigma'} \sum_{\langle\langle Y, W_j \rangle\rangle} [i \hat{s} \times \mathbf{d}_{Y, W_j}]_{\sigma\sigma'} [\text{Re}(\Lambda_f^{YW}) \\ &+ i \nu_{Y, W_j} \text{Im}(\Lambda_f^{YW})] |Y \sigma\rangle \langle W_j \sigma'| + \text{H.c.} \\ &+ \Lambda_f^{ZZ} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle Z_j, Z_k \rangle\rangle} [i \hat{s} \times \mathbf{d}_{Z_j, Z_k}]_{\sigma\sigma'} |Z_j \sigma\rangle \langle Z_k \sigma'| \\ &+ i\Lambda_f^{YZ} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle Y, Z_j \rangle\rangle} [\hat{s} \times \mathbf{d}_{Y, Z_j}]_{\sigma\sigma'} |Y \sigma\rangle \langle Z_j \sigma'| + \text{H.c.} \\ &+ i\Lambda_f^{OZ} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle O, Z_j \rangle\rangle} [\hat{s} \times \mathbf{d}_{O, Z_j}]_{\sigma\sigma'} |O \sigma\rangle \langle Z_j \sigma'| + \text{H.c.} \end{aligned} \quad (86)$$

C. Adatom in bridge position

Oxygen and nitrogen are theoretically predicted to bond in the bridge position [94]. However, also for impurities in the top position like copper [37,96,97] and gold [90,97] the energy difference between the top and bridge configurations is relatively small and therefore their bridge realization becomes quite probable. Similarly, the light adatoms like CO, NO and NO₂ prefer to adsorb [92] equally likely to the hollow and bridge positions. For those reasons, we discuss in this section an effective SOC Hamiltonian that works for light adatoms in the bridge configuration. Particularly, by bridge we understand a configuration when the adatom O splits a nearest-neighbor bond between two— Y_1 and Y_2 —carbon sites, see Fig. 11. Such a structure possesses C_{2v} point group symmetry, which comprises two nonequivalent reflection planes Σ_d^{xz} and Σ_v^{yz} , and C_2 rotation around the axis of their intersection; see Fig. 11. As the order of this group is lower compared to the above cases we expect more SOC mediated matrix elements which in general would be complex-valued. Even within the approximation that keeps only nearest and next-nearest-neighbor hoppings among O , Y , and Z sites, the

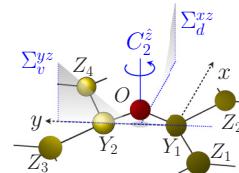


FIG. 11. Adatom bonded in the bridge position with a center of symmetry on the vertical axis passing the adatom: the local point group symmetry C_{2v} , atom labeling convention, axes orientations, and C_{2v} group operations as discussed in the main text.

effective SOC Hamiltonian contains eight hoppings. Three of them are spin-conserving (and hence purely imaginary) and the remaining five are spin-flipping,

$$i\Lambda_c^{YZ} = \langle Y_2 \uparrow | \hat{H}_{\text{so}} | Z_4 \uparrow \rangle, \quad (87a)$$

$$i\Lambda_c^{OZ} = \langle O \uparrow | \hat{H}_{\text{so}} | Z_4 \uparrow \rangle, \quad (87b)$$

$$i\Lambda_c^{ZZ} = \langle Z_1 \uparrow | \hat{H}_{\text{so}} | Z_2 \uparrow \rangle, \quad (87c)$$

$$i\Lambda_f^{OY} = \langle O \uparrow | \hat{H}_{\text{so}} | Y_1 \downarrow \rangle, \quad (87d)$$

$$i\Lambda_f^{YY} = \langle Y_1 \uparrow | \hat{H}_{\text{so}} | Y_2 \downarrow \rangle, \quad (87e)$$

$$\text{Re}(\Lambda_f^{YZ}) + i \text{Im}(\Lambda_f^{YZ}) = \langle Y_2 \uparrow | \hat{H}_{\text{so}} | Z_4 \downarrow \rangle, \quad (87f)$$

$$\text{Re}(\Lambda_f^{OZ}) + i \text{Im}(\Lambda_f^{OZ}) = \langle O \uparrow | \hat{H}_{\text{so}} | Z_4 \downarrow \rangle, \quad (87g)$$

$$\Lambda_f^{ZZ} = \langle Z_2 \uparrow | \hat{H}_{\text{so}} | Z_1 \downarrow \rangle. \quad (87h)$$

Let us shortly comment on three of the above emerging couplings—Eqs. (87a), (87f), and (87g). The absence of the translational invariance allows spin-conserving hopping $i\Lambda_c^{YZ}$ between the nearest-neighbor sites Y and Z —similar coupling was encountered in the local C_{6v} case for the adatom in hollow position. For the same reason, there are the spin-flip hoppings Λ_f^{YZ} —among the nearest neighbors—and Λ_f^{OZ} —among the next-nearest neighbors and both are complex-valued in general.

Altogether, we can write the local Hamiltonian for the local C_{2v} symmetric structure in a closed form, with the help of the definitions that we introduced above, as follows:

$$\begin{aligned} \mathcal{H}_{\text{so}}^{\text{brid}} = & i\Lambda_c^{YZ} \sum_{\sigma} \sum_{\langle Y_j, Z_k \rangle} v_{O, Z_k} [\hat{s}_z]_{\sigma\sigma} |Y_j \sigma\rangle \langle Z_k \sigma| + \text{H.c.} \\ & + i\Lambda_c^{OZ} \sum_{\sigma} \sum_{\langle\langle O, Z_k \rangle\rangle} v_{O, Z_k} [\hat{s}_z]_{\sigma\sigma} |O \sigma\rangle \langle Z_k \sigma| + \text{H.c.} \\ & + i\Lambda_c^{ZZ} \sum_{\sigma} \sum_{\langle\langle Z_j, Z_k \rangle\rangle} v_{Z_j, Z_k} [\hat{s}_z]_{\sigma\sigma} |Z_j \sigma\rangle \langle Z_k \sigma| \\ & + i\Lambda_f^{OY} \sum_{\sigma \neq \sigma'} \sum_{\langle O, Y_j \rangle} [\hat{s} \times \mathbf{d}_{O, Y_j}]_{\sigma\sigma'} |O \sigma\rangle \langle Y_j \sigma'| + \text{H.c.} \\ & + i\Lambda_f^{YY} \sum_{\sigma \neq \sigma'} [\hat{s} \times \mathbf{d}_{Y_1, Y_2}]_{\sigma\sigma'} |Y_1 \sigma\rangle \langle Y_2 \sigma'| + \text{H.c.} \\ & + \sum_{\sigma \neq \sigma'} \sum_{\langle Y_j, Z_k \rangle} [v_{O, Z_k} [i\hat{s}_y]_{\sigma\sigma'} \text{Re}(\Lambda_f^{YZ}) + i \text{Im}(\Lambda_f^{YZ})] \\ & \times \text{sgn}[\mathbf{d}_{O, Y_j} \cdot \mathbf{d}_{Y_1, Y_2}] |Y_j \sigma\rangle \langle Z_k \sigma'| + \text{H.c.} \\ & + \sum_{\sigma \neq \sigma'} \sum_{\langle\langle O, Z_j \rangle\rangle} [v_{O, Z_j} [i\hat{s}_y]_{\sigma\sigma'} \text{Re}(\Lambda_f^{OZ}) + i \text{Im}(\Lambda_f^{OZ})] \\ & \times \text{sgn}[\mathbf{d}_{O, Z_j} \cdot \mathbf{d}_{Y_1, Y_2}] |O \sigma\rangle \langle Z_j \sigma'| + \text{H.c.} \\ & + \Lambda_f^{ZZ} \sum_{\sigma \neq \sigma'} \sum_{\langle\langle Z_j, Z_k \rangle\rangle} [i\hat{s} \times \mathbf{d}_{Z_j, Z_k}]_{\sigma\sigma'} |Z_j \sigma\rangle \langle Z_k \sigma'|. \end{aligned} \quad (88)$$

In the first and sixth lines, in which we are summing over the nearest neighbors $\langle Y_j, Z_k \rangle$, the symbol v_{O, Z_k} has the following meaning; it equals 1 (−1) if the path $Z_k \rightarrow Y_j$ after extension

to the next-nearest-neighbor path $Z_k \rightarrow Y_j \rightarrow O$ becomes counter clockwise (clockwise).

V. FINAL REMARKS AND CONCLUSION

As already noted, the lower the symmetry, the more SOC parameters enter the effective model Hamiltonians. Before applying a particular model to spin-transport studies, two issues should be resolved. First, figure out the realistic strengths of SOC parameters and, second, reduce the number of the parameters as much as possible. For that, one should employ first-principles calculations together with physical intuition and common sense.

To describe our strategy, we start with *ab initio* calculations considering a large graphene supercell with one adatom bonded in a given configuration. The larger the supercell, the weaker are the interactions among the periodic images, and the more representative the dilute coverage limit is realized. Analyzing local DOS and its atomic orbital decomposition, we directly test whether the system can be properly described by the adequate Hamiltonian model, i.e., carbon π orbitals and an effective adatom level. In all the cases yet analyzed—hydrogen [34], fluorine [35], CH_3 group [36], and copper [37] (both in top and bridge configurations)—the effective models with effective adatom orbitals work perfectly. For example, for fluorine [35] the remaining $2p$ orbitals contribute to electronic bands far below the Fermi level, and hence the low-energy physics is dominated by $2p_z$ orbital. Fitting the spin-orbit induced band splittings would give us the strengths of the sought SOC parameters. The aim is to find a minimal set of best-fitting parameters to keep the model simple and simultaneously capture the main features in SOC induced band splittings. It might not be necessary to take into account all the symmetry-allowed coupling parameters. For that some intuition, experience and an input from the DFT are helpful, e.g., the possibility to turn off in first-principles calculations SOC interaction on the adatom, or shift away the Fermi level Bloch states composed from the (un)wanted atomic orbitals [98]. All that helps to trace the importance and interpretation of the effective spin-orbit couplings. Table III summarizes the relevant spin-orbit couplings including their strengths as taken from Refs. [34–37]. The general tendency is obvious, the heavier the adatom, the stronger are the local SOC parameters. Comparing their strengths with respect to the graphene intrinsic SOC, we see that hydrogen and methyl enhance local SOC by two orders of magnitude, fluorine by three orders, and copper enhances local SOC by four orders of magnitude.

There have already been studies constructing model SOC Hamiltonians induced by adatoms in graphene [40, 58]. Our approach to the Hamiltonian building is different from those, so it is not surprising that the forms of the Hamiltonians also differ. The analysis of Weeks *et al.* [40] focuses on heavy adatoms adsorbed in hollow positions interacting with graphene through three outer p -shell orbitals of the adatom. The fine structure of these orbitals, due to the intra-atomic spin-orbit coupling, gives rise, via hybridization with carbon orbitals, to the induced SOC of the π band of graphene. The procedure to integrate out (downfold) the adatom orbitals starts from a fully functionalized graphene with global C_{6v} symmetry—adatoms are occupying each hexagon—but with

TABLE III. Summary of local SOC strengths for different adatoms: hydrogen, fluorine, methyl, and copper [34–37]. Let us emphasize that compared to the referred manuscripts and notation used therein— Λ_I^A , Λ_I^B , Λ_{PIA}^B , and Λ_R —we renamed and also properly rescaled their strengths to match the present convention. A translation between the new and old notations is as follows: $\Lambda_c^{YW} = \Lambda_I^A/(3\sqrt{3})$, $\Lambda_c^{ZZ} = \Lambda_I^B/(3\sqrt{3})$, $\Lambda_f^{ZZ} = 2\Lambda_{PIA}^B/3$, and $\Lambda_f^{YZ} = 2\Lambda_R/3$.

Adelement/SOC (meV)	Λ_c^{YW}	Λ_c^{ZZ}	Λ_I^{ZZ}	Λ_I^{YZ}	Λ_f^{YY}	Λ_f^{YZ}	Λ_f^{OZ}
Hydrogen (top) [34]	−0.04	−	−0.51	0.22	−	−	−
Fluorine (top) [35]	−	0.64	4.87	7.47	−	−	−
Methyl (top) [36]	−0.15	0.03	−0.46	0.68	−	−	−
Copper (top) [37]	−	1.73	31.6	20.1	−	−	−
Copper (bridge) [37]	−	−	−	−	41.0	−7.5	7.4+i8.4

no direct coupling between the orbitals on neighboring adatoms. In contrast, our approach treats a single adatom, so the system has only a local symmetry. Our Hamiltonian for the hollow position thus differs from the one obtained in Ref. [40]. In the work of Pachoud *et al.* [58], all three relevant adatom configurations are considered, and the choice of the adatom orbitals is not restricted. However, the form of the Hamiltonians is limited to the spatial delta-function (at the adatom site) multiplied by an 8×8 matrix to cover the pseudospin, valley, and spin spaces. The local structure is thus not preserved, which is not a problem in the continuum limit. Our models instead keep all the local symmetries that adatoms induce (or, rather, still preserve), by assigning pseudospin, spin, and valley-dependent hopping elements in the close neighborhood of the adatom site.

In summary, we have provided in full detail a derivation of effective SOC Hamiltonians for hexagonal systems employing group theory analysis. Our results cover several experimentally relevant scenarios: (i) global SOC effects caused by the proximity of substrates, such as transition metal dichalcogenides,

or metallic interfaces; and (ii) local SOC effects due to dilute adatom or admolecule functionalization with emphasis on hollow, top, and bridge adsorption positions. For both cases (i) and (ii), we have explicitly shown which effective SOC matrix elements are suppressed by the presence or absence of particular symmetries and classified the SOC mediated hoppings by the subgroups of the full hexagonal point group. In general, our construction-oriented approach is easily transferable to systems with other symmetries and allows one to derive quickly a particular effective SOC Hamiltonian respecting the given symmetries. Such effective SOC Hamiltonians serve as useful ingredients for model calculations that investigate transport, (quantum) spin Hall effect, spin relaxation and dephasing, WL/WAL measurements, etc.

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